Section 6 Technical Data

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Specifications

Performance

Frequency response: ±0.25Hz below compressor, de-esser, or gate threshold, 20-

20,000Hz.

RMS noise: >85dB below output clipping level.

Installation

Audio Input - Line Level, Effects Receive Port

Impedance: >10kΩ load impedance, electronically balanced. Balanced source ≤600Ω

recommended (not required).

Sensitivity: Can be used with nominal levels from -10dBu to +8dBu.

EMI suppressed: Yes.

Connector: XLR and Barrier strip (Barrier strip only for Effects Return) (#5 screws).

Audio Input – Mic Level (with optional mic preamp)

Impedance: 1500Ω load impedance, transformer balanced. Selectable -20dB pad. Sensitivity: Can be used with nominal levels from -65dBu to -10dBu (with pad).

EMI suppressed: Yes.

Connector: XLR.

Audio Output - Line Level

Impedance: 30Ω source impedance, electronically balanced and floating to simulate transformer output. Output can be unbalanced by grounding one output terminal.

Output level: Adjustable for use with -10dBm to +8dBm (into 600Ω) systems.

Output clipping level: >+20dBm into 600Ω .

EMI suppressed: Yes.

Connector: XLR and Barrier strip (#5 screws).

Audio Output — Mic Level

Impedance: 200Ω , balanced. Level: -55dBm into 600Ω .

Audio Output — Effects Send Port

Impedance: 47Ω , single-ended.

Level: +4dBm into 600Ω .

Power

Power requirement: 115/230V AC (±10%), 50-60Hz, 16VA.

Connector: IEC mains connector with 3-wire "U-ground" or CEE7/7 power cord and

plug.

EMI suppressed: Yes.

Fuse: 1/2-amp 3AG 250V Slow-Blo fuse for 115-volt operation; .250-amp "T" type 250V fuse for 230-volt operation.

Physical

Dimensions: 19 inches (48.3 cm) wide, $11^{1}/_{4}$ inches (28.5 cm) deep, $3^{1}/_{2}$ inches high. 787SL is $1^{3}/_{4}$ inches (4.5 cm) high.

Operating temperature range: 32-113°F (0-45°C)

Humidity: 0-95% relative humidity, non-condensing.

Options

MIDI interface: For sending data and commands between units — see page 3-14. Order RET045.

RS-232 interface: For sending data and commands between units — see page 3-17. Order RET050.

Mic preamp: Raises mic-level inputs to line level. Order RET046.

Basic remote control accessory: For remote control of UP, DOWN, RECALL, and SELECT CHANNEL. Displays preset number. Order ACC024.

Security cover (acrylic): To prevent unauthorized adjustment of controls — see page 3-12.

Circuitry

Compressor

Attack time: approximately 5 ms; program dependent.

Release time: adjustable between approximately 1dB/sec to 50dB/sec; linear release

rate.

Compressor ratio: ∞ to 1

Range of gain reduction: 25dB.

Interchannel tracking with 787ASL: ±0.5dB, STEREO COUPLED.

Total harmonic distortion: <0.1% at 1kHz (release time = 2.5dB/sec, 15dB gain

reduction). Typically <0.1% at 20Hz, <0.05% from 100-20,000Hz.

SMPTE intermodulation distortion: <0.05% (60/7,000Hz 4:1; 15dB gain reduction;

release time = 2dB/sec).

Gain reduction element: Class-A proprietary VCA.

Equalizer

Type: 3-band parametric.

Equalization range: +16, -40dB.

Tuning range: 30-632Hz, 210-7,650Hz, 420-15,300Hz.

Bandwidth range: (at 8dB boost) 0.1-5 octaves (Q = 0.3-12.5).

Overload Indicator: Lights for 200ms if the instantaneous peak output of any

amplifier rises to within 1dB of its clipping point.

De-Esser

Attack time: Approximately 200ms. Release time: Approximately 200ms.

Available attenuation: 25dB.

Noise Gate

Hold time: Approximately 250ms.

Attack time: Approximately 200ms.

Release time: <0.1ms.

Available attenuation: 25dB.

Memory

Capacity: 99 user-programmable registers for host unit; 99 user-programmable

registers for slave unit.

Back-up: 5 year lithium battery.

Warranty

One year, parts and labor: Subject to limitations set forth in our Standard Warranty.

All specifications subject to change without notice.

Circuit Description

On the following pages, a detailed description of each circuit's function is accompanied by a component-by-component description of that circuit. Keywords are highlighted throughout the circuit descriptions to help you quickly locate the information you need.

This section begins with an overview of the 787A circuitry, and then provides a description of the digital and analog control circuitry.

Digital control circuitry is described in 9 major blocks: clock circuitry, power monitoring circuitry, basic microcomputing circuitry, display driver circuitry, switch decoding circuitry, digitally-controlled analog processing circuitry, MIDI option, RS-232 option, and remote control option.

Analog audio circuitry is described in 13 major blocks: input buffer, input attenuator, VCA (voltage-controlled amplifier), equalizer, compressor control, noise gate control, de-esser control, PEAK OUTPUT LEVEL metering, effects send and receive, overload indicator, power supply, and optional microphone pre-amp.

Overview

The Programmable Mic Processor is an analog signal processing device controlled by a microprocessor. The microprocessor and associated digital circuitry allow instant and repeatable modification of the analog signal processing. 99 user-definable processing settings are stored in battery backed-up RAM. These are called PRESETS and can be recalled at any time via front panel switches, rear panel contact closures, serial communications link (MIDI or RS-232), or with the REMOTE CONTROL unit. The presets are created using simple front panel keys and the LED displays. The microprocessor interprets and controls the activity of these input devices.

The parameters of the analog processing circuitry are set with Digital to Analog Converter (DAC) ICs. The DACs are controlled by the Z-80 microprocessor. The DACs are written to an 8-bit word and then clocked to latch the word in its internal register. This word adjusts the DACs internal resistor ladder network which is part of the analog circuit, thus altering a parameter of the analog circuit.

To set the operating parameter for a DAC, the Z-80 writes the data and address for the DAC to a pair of latches on the DIGITAL PCB. This isolates the analog cicuitry from the digital circuitry and the noise it generates.

The latches buffer the data and address lines and drive the ribbon cable connecting the two boards. The data line on the **analog board** directly connects to the DACs. Address decoders receive the address from the **digital board** and select the DAC to read the data. The DAC latches the data when clocked by the address decoder so the Z-80 can load the next DAC with data.

1. Digital Circuit Description

1. Overview

A Z-80 microprocessor is the central controller of the 787A. The basic functions of the Z-80 and its supporting digital circuitry decode the switches, drive the displays, set the analog processing circuitry, and store and retrieve the operating parameters and presets in memory.

2. Clock Circuitry

The clock circuit provides a 4MHz signal to the clock input of the Z-80 microprocessor and any serial board connected to the system. This provides the timing and synchronization necessary to make the digital circuitry work correctly.

Component-level description:

An 8MHz crystal Y1 is the feedback element in an inverter oscillator circuit consisting of inverter IC2a and loading and phase-shift compensation components R1, R2, C1, and C2. The 8MHz output at IC2b pin 4 is then buffered by IC2c, then divided by 2 with flip-flop IC3a. This 4MHz signal appears at the output of IC3a pin 5 and is then buffered by IC2d to provide the clock signal required by the Z-80 microprocessor. IC13b divides the buffered 8MHz clock signal at pin 6 IC2c to 4MHz and provides the inverted phase to drive the serial board.

3. Power Monitoring Circuitry

A voltage level sensing circuit monitors the regulated +5 volts. This circuit shuts down the Z-80 and protects the contents of the RAM when the voltage falls below 4.5 volts.

Component-level description:

The +5 volt supply is scaled with voltage divider R9 and R10 to 1.34 volts. This voltage is compared to a 1.2 volt precision reference diode CR1 with biasing resistor R12. When the +5 volt supply drops below 4.5 volts the output of IC13b pin 1 goes low and quickly discharges C3. Hysteresis is provided by R11 with CR2 to prevent current from flowing back to the input of IC13b. IC8a and IC8b double buffered this signal to obtain the correct polarity to enable the RESET pin 26 of the Z-80 microprocessor. The Z-80 will halt when the RESET pin of the Z-80 is set low. When +5 volts recovers to above 4.5 volts, IC13b pin 1 will go open collector allowing R13 to charge

C3. This triggers IC8a and IC8b to disable the RESET pin. The Z-80 will then re-initialize itself.

The RESET signal at IC8 pin 6 also disables the RAM chip IC7 at CE2 pin 26. CE2 low prevents any data from being written to the RAM. This prevents any data from becoming corrupt when +5 volts falls below the operating voltage of the circuit. The RESET signal also goes to J5 to reset appropriate ICs on any serial boards that are connected.

To prevent erratic display messages, the output of IC8a provides the DISPLAY BLANK signal to blank all of the front panel LEDS and displays except for the overload LEDS when the +5 volt supply is not in its correct operating range. Q3 is used as a low leakage diode to isolate IC8 from circuits on the display board which are not powered by the battery. R36 is a pull-up resistor.

The front panel RESET switch also activates the RESET condition described above. When the switch is pressed, C4 discharges through R15 which sets pin 2 of NAND gate IC8b low. This causes its output to go low, enabling the RESET signal.

4. Microcomputing Circuitry

The microcomputing circuitry consists of the Z-80 microprocessor, a random access memory (RAM) IC, a read only memory (ROM) IC, latched buffers, and other logic devices.

The Z-80 is the central computing device and controls the states of the other components. The software program in the ROM determines what operations the Z-80 will execute.

The digital board features two sections; memory and input/output. The memory section allows the Z-80 to access ROM and RAM. The input/output section allows access to the devices off the digital board: digital-controlled analog components, switches, displays, MIDI and RS-232.

Component-level description:

The MREQ (pin 19) of IC4 goes low when a memory function is executed. This signal enables the memory address decoder IC5 which selects the proper memory device to be accessed by the Z-80. If the address is in the range of 0000H to 4000H, pin 15 or pin 14 of IC5 will clock low. These outputs are ANDed together by AND gate IC9b and pin 6 will go low if either of its inputs are low. This will select ROM IC10. If the address is in the range of 4001H to 6000H IC5 pin 13 will clock low selecting RAM IC7. The WR (pin 22) of IC4 determines if the RAM is to be read from (high) or written to (low).

The I/O REQ (pin 20) IC4 goes low to access the input/output devices. This line allows IC6 to decode the address of the device being accessed. The address range of the input/output devices are from 0 to 100H. Address locations 0 to 1FH select the DAC buffered latches IC12 and IC14. 20H selects DACSELA. 21H selects DACSELB. 60H selects the serial port enable line MIDI. 80H with WR selects SWWR to write to the switch matrix. 80H with RD selects SWRD to read the switch matrix. C0H selects the DISPLAY CHARACTER control line. E0H selects the DISPLAY SEGMENT control line.

5. Display Circuit

A constant current driver circuit multiplexed by the microprocessor drives the 4 numeric displays and most of the discrete LEDS on the front panel. There are 8 discrete constant current sources to drive up to 8 led segments or individual LEDs at each multiplexed time slot. There are eight sets of 8 segments or individual LEDs being multiplexed. Each of these sets is called a character.

Component-level description:

The constant current source consists of Q1–Q11, CR1–CR10, R1–R29, and C14. R1, CR1, and R2 set a constant current through Q1. The voltage at the emitter of Q1 and R4 determine this current. This current causes a voltage drop across R3 which is referenced to +8 volts (TP2). This voltage appears at TP1 buffered by Q2 and Q3 and filtered by C14. R5 biases Q2 and Q3 and CR2 prevents reverse biasing of the transistors.

There are eight constant current elements with outputs labeled A-H. These outputs are connected directly to the segments of the numeric displays and to the LEDs.

The voltage at the emitter of each segment driver transistor (Q4—Q11) determines the magnitude of the drive current. This voltage equals the voltage at TP1.

Each output transistor is turned on by drawing a base current through its corresponding $3.3k\Omega$ base resistor. This current is sinked by transistor array IC4. The transistors in IC4 are driven by latch IC3. A high bit at the output of IC3 selects the character by turning on the corresponding transistor in IC4.

IC5 and IC6 select the character to be driven in a given time slot. The 787 multiplex rate is approximately 14.5 msec, or 1.8 msec per character. The data is set at input ports 1D to 8D of IC5. Pin 11 is then clocked to load the latch. IC5's latched outputs drive IC6 which is a package of 8 open collector NPN transistors. These transistors each drive a character consisting of up to 8 segments or discrete LEDs. A high bit at the output of IC5 selects the character by turning on the specific transistor in IC6. The outputs of IC6 go low to sink current through the desired segment from the 8 constant current sources.

6. Switch Decoding

The microprocessor decodes the front panel switches and the internal LOCKOUT RESET switch. The switches are arranged in a matrix so that a software algorithm can determine which if any of the switches are closed. The matrix is organized into 7 rows and 3 columns.

Component-level description:

The first step to decode the switches is to set all of the row drivers low with 8-bit latch IC16, and then to read the columns with buffer IC15. A closed switch causes the column the switch is connected to go low. If no switches in that column are closed, pull-up resistors R21a-R21g pull the column inputs

high. If the microprocessor finds that there are switches closed, it sets one row low at a time and reads the column inputs. By knowing which row and column is low the microprocessor can determine which switch is closed

IC15 and IC16 are also used to determine if any options are installed at the serial port J5, if the 787ASL slave chassis is connected, and if the slave is in the STEREO COUPLE position.

Options are detected much in the same way as the switch decoding scheme described above. Columns 1–3 are shared with the front panel switch circuitry, so the status of the options are only checked when none of the switches are closed. OPTION DETECT pin 12 of IC16 is a row driver. However, instead of switches being connected, diodes are installed on the option boards so that when the OPTION DETECTline goes low, the corresponding diode will pull its column low. Column 1 is used to detect the MIDI or RS-232 option. Column 2 detects the 787ASL. Column 3 checks if the slave is in the STEREO COUPLE mode.

The rear panel remote closure contacts are also read through IC15. These switches are not in a matrix. Each of the four switches has its own input port with IC15. Each connection to the terminal block has the same RF protection as the audio inputs, a .001uF capacitor chassis bypass and two ferrite beads. R17–R20 are in series with the inputs to current limit. To prevent excessive voltages from damaging internal circuitry CR5–10, CR15, CR16 clamp input voltages from exceeding +5.6 volts or -.6 volts.

The 3 volt RAM back-up battery is also monitored. IC13b compares the voltage of the battery to the voltage produced by divider R22 and R23. When the voltage of the battery falls below +2.5 volts, pin 14 of IC13 goes low. This output is read by the microprocessor at pin 8 of IC15. The decimal point of display 4 will blink when this condition is detected to warn the user that the battery needs to be replaced.

7. Digital-controlled Analog Processing Circuitry

These parameters of the analog processing circuitry are set with Digital to Analog Converters (DAC) ICs: INPUT GAIN, compressor RELEASE TIME, GATE THRESHOLD, NOISE GATE DEPTH, equalizer BOOST/CUT, CENTER FREQUENCY, and BANDWIDTH, DE-ESSER THRESHOLD, and EFFECTS RETURN LEVEL. The DACs are controlled by the Z-80 microprocessor. The DACs are written to an 8-bit word and then clocked to latch the word in its internal register. This word adjusts the DACs internal resistor ladder network which is part of the analog circuit, thus altering a parameter of the analog circuit.

Component-level description:

The Z-80 sends the address of the DAC to be accessed and the data to be written to it with latches IC12 and IC14. IC12 and IC14 are 8-bit latches that buffer the data and address busses from the digital board to the analog board. This prevent the high frequency noise present on the digital board busses from entering into the audio path on the analog board since the outputs of IC12 and IC14 only change state when new data is written to a DAC.

Pin 11 of IC12 and IC14 are clocked high simultaneously to set the address and data at the inputs of the IC's to their internal registers. The word stored

in the register of the latch is seen at its output because the OUTPUT ENABLE pin 1 is held low for both IC12 and IC14.

Control lines DACSELA and DACSELB are decoded with IC1 and connect directly to the analog board. DACSELA is used to enable the 787A DAC decoding circuitry on the analog board. DACSELB sets the 787ASL DAC decoding circuits. These control lines clock low after IC12 and IC14 have been loaded with the data and address.

This completes the discussion of the digital control lines from the digital board. The following discussion describes the Digital Control Logic on the analog board.

The data from IC12 is directly connected to all of the DACs and the address data from IC14 is sent to address decoders IC22, IC23, IC24, and IC25. The address data, plus the state of either DACSELA or DACSELB, enables the decoders to determine which DAC is selected to receive new data. One of the output pins of IC22, IC23, or IC24 clocks high to set the latch of the desired DAC. The DAC immediately changes the settings of its resistor ladder network to that directed by the new data.

8. MIDI Option:

The MIDI option is based on a serial input/output (SIO) IC and a counter timer chip (CTC) IC. The SIO IC provides serial to parallel and parallel to serial conversion. The CTC IC provides the transmit/receive clock for the SIO.

Component-level description:

The RESET signal from the DG board resets IC1 (pin 21) and IC6 (pin 17) whenever the Z-80 is reset.

CR2 is part of the **Option Detect** circuit described in the **Switch Decoding** section. CR2 allows the Z-80 to determine if the MIDI board is present.

The 4 megahertz clock from the DG board is buffered by IC2a and IC2d to drive IC1 pin 20 and IC6 pin 15. This clock allows synchronized communication between the Z-80 and the SIO and CTC IC's. IC2b, IC2c, and IC3f provide address decoding so the Z-80 can select either the CTC (IC6 pin 10 and 16) or the SIO (IC 1 pin 35 and 36).

IC7a divides the 4 megahertz clock to 2 megahertz, which appears at pin 5. The CTC generates the 31.5kHz transmit/receive clock for the SIO from the 2 megahertz signal. The 31.5kHz signal is seen at IC6 pin 7. This output drives IC1 pin 13 and 14.

The SIO receives data to be transmitted from the Z-80 on the 8-bit data bus labeled DB0-DB7. When the CE and IORQ (pins 35 and 36) are low in conjunction with RD the data is written to the SIO. This data is transmitted out serially at TxDa (pin 15). This output is buffered by IC3b which drives IC4b. IC4b is an open collector inverting buffer which provides the current driver for the MIDI current loop.

The MIDI current loop presents the diode of an opto-isolator between pins 4 and 5 of J3 with the anode connected to pin 4. Thus the transmitted signal

will not be seen at the MIDI OUT connector (J3) unless a MIDI device is connected to J3.

Serial data is received from the MIDI IN port (J1). R7 and IC5 are elements of a current loop. IC5 is a high gain opto-isolator with gain set by R12. Pin 6 of IC5 goes low when current passes through pins 2 and 3. R1 pulls pin 6 to +5 volts when there is no current in the loop. The signal at IC5 pin 6 is buffered by IC3d and IC3e. IC3e drives the receive data (RxDa pin 12) of IC1.

IC3e also drives the MIDI THRU port (J2). The MIDI THRU port operates the same as the MIDI OUT port described above.

9. RS-232 Option

The RS-232 option is based on a serial input/output (SIO) IC and a counter timer chip (CTC) IC. The SIO IC provides serial to parallel and parallel to serial conversion. The CTC IC provides the transmit/receive clock for the SIO.

Component-level description:

The RESET signal from the DG board resets IC7 (pin 21) and IC6 (pin 17) whenever the Z-80 is reset.

CR1 is part of the Option Detect circuit described in the Switch Decoding section. CR1 allows the Z-80 to determine if the RS-232 board is present.

The 4 megahertz clock from the DG board is buffered by IC1b and IC1c to drive IC7 pin 20 and IC6 pin 15. This clock allows synchronized communication between the Z-80 and the SIO and CTC IC's. IC5a, IC5d, and IC1e provide address decoding so the Z-80 can select either the CTC (IC6 pin 10 and 16) or the SIO (IC7 pin 35 and 36).

IC1a, Y1, C9, C10, R4, and R5 define a 6.144MHz oscillator circuit. The 6.144MHz clock signal appears at pin 2 IC1a. This signal is buffered by IC1f and then divided to 1.5285MHz by IC2a and IC2b. This signal drives pin 23 of IC6. The CTC generates the transmit/receive clock at the selected baud rate for the SIO from the 1.5285MHz signal. The clock signal at the selected baud rate is seen at IC6 pin 7. This output drives IC7 pin 13 and 14.

The SIO receives data to be transmitted from the Z-80 on the 8-bit data bus labeled DB0-DB7. When the CE and IORQ (pins 35 and 36) are low in conjunction with RD the data is written to the SIO. This data is transmitted out serially at TxDa (pin 15). This output drives the line interface IC IC4b. RTS (pin 17) and DTR (pin 16) are control lines which control the RS-232 communication protocols.

Serial data is received from the RS-232 connector (J1) at pin 2. IC3a is the receive buffer which drives the SIO RxDa input (pin 12). The serial data is converted to an 8-bit word and sent to the Z-80 on the data bus labeled DB0-DB7.

C1 and C4 are high frequency bypass capacitors to prevent oscillation on the ± 22 volt supply. C2 and C9 are filter capacitors. C3 and C6 are output bypass capacitors. IC9 and IC8 are ± 12 volt regulators which supply the

source voltages to drive the RS-232 outputs (J1 pins 3, 5, and 6) at the correct voltage levels.

10. Remote Control Option

The remote control circuitry allows for data from the Digital Board to be sent and received serially from the internal remote PCB to the external remote unit. This data will be interpreted at the remote external PCB to control the displays and LEDs and allow for the digital board to determine what keys have been pressed on the remote unit.

Component-level description:

Internal Remote Circuit

Data bit D0 is buffered by IC1d and present at the D inputs of flip-flops IC3a and IC3b. The data will appear inverted at the \overline{Q} outputs of one of the flip-flops when IC1a and IC1b decode $\overline{\text{MiD1}}$ and A0 and clocks the flip-flop. This signal will then be level shifted by open collector inverters IC5a or IC5b. Pull-up resistors on the external remote PCB will allow the outputs of these inverters swing between 0 and +15 volts. R2 and R6 are for current limiting and work with C11 and C16 for signal shaping.

The signal at RD0 is level shifted by R7 and R8 and will appear at pin 9 of IC4b. CR2 assures that this signal will not exceed +5.6 volts. IC2b and IC2c buffer this signal. Data is read from pin 8 IC2c when IC1c decodes MIDI and RD to enable buffer IC4b.

Regulator IC6 provides the +15 volts for the external remote circuitry. C4, C5, and C6 provide frequency compensation for IC6. R3 provides a discharge path for C5 when the external unit is not connected. CR1 prevents IC6 from becoming reversed biased.

Capacitors C6-C16 with ferrite beads FB1-FB4 prevent high frequency noise from being radiated from the unit.

External Remote Circuit

C1, C2, C8, and C9 with FB1-FB4 provide RF filtering for the four wire connection to the Internal Remote PCB. R3 and R4 are pull-up resistors and R1 and R2 provide current limiting. CR1-CR4 prevent the voltage on RD0 and RD1 from going above +15 volts or below 0 volts.

Data received on RD0 and RD1 is buffered by IC6b, IC6c, IC7d and IC7d. Binary counter IC1 counts the pulses received on RD0 when RD1 is high. RD1 goes low to clock flip-flops IC3a, IC3b, and IC2b to latch the current count of IC1 at the flip-flops. RD1 low will also clear the current count of IC1. The outputs of the flip-flops are used to address either one of the switches, SW1-SW4; one of the displays, D1-D2; or the LEDs.

IC8 decodes the address from the flip-flops and selects binary counter IC5 to enable counting by IC6a. This count will be decoded by BCD to 7 segment drivers IC10 or IC4 and displayed on D1 or D2 when pin 5 is clocked setting the drivers latch. R21-R34 are current limiting resistors to set the displays segment current. BCD to 7 segment driver IC11 is selected by

IC8 to drive the discrete LEDs. Flip-flop IC2a pin 1 is set to +5 volts when the IC1 counts to 9 and triggers IC6d low. This signal is inverted by IC7b which sets flip-flop IC2a. Pin 1 of IC2a will drive R13 to turn on transistor Q1 to enable the LEDs contained in SW1-SW3.

2. Analog Circuit Description

1. Overview

The block diagram on 6-41 illustrates the following overview of 787A circuitry.

The line level input signal enters the 787A in balanced form receiving moderate RFI suppression. It is then applied to a very low-noise opamp configured as an "active transformer."

The microphone pre-amp input signal is applied to an input transformer. This signal is then fed to an opamp circuit with gain and summed with the line level input

The three bands of equalization are created by a state variable topology. This provides very stable operating characteristics. Constant "Q" is maintained when boost/cut, center frequency, or bandwidth is adjusted. Notching capabilities are provided.

The current-controlled gain block used in the 787A is a proprietary class-A voltage-controlled amplifier (VCA). It operates as a two-quadrant analog divider with gain inversely proportional to a current injected into a first gain-control port, and is cascaded with a two-quadrant analog multiplier with gain directly proportional to a current injected into a second gain-control port. Any "thumps" due to control current feedthrough are eliminated by applying DC to offset to the VCA's input.

The compressor is a feedback circuit: the output of the compressor is looped back to develop a gain-control signal that is applied to the VCA. This arrangement results in superior stability of characteristics with time and temperature, extremely LOW distortion, and optimized control-loop dynamic response.

The proprietary compressor **timing module** generates a control signal that enables the 787A to achieve natural-sounding control and very low modulation distortion. The RELEASE TIME control allows a 50:1 variation in the basic release dynamics. The release dynamics are determined by the **timing module** on the basis of the past history of the input.

Release time circuitry allows the recovery to proceed at a constant rate (in dB/second) regardless of the absolute gain reduction.

A gating detector monitors the level of the 787A's input signal, and activates the compressor gate or compressor and noise gate if this level drops below a threshold set with the GATE THRESHold control.

When the NOISE GATE is enabled the output of the 787A will be attenuated by the amount selected with the DEPTH control.

The DE-ESSER detects sibilance in the region of 6kHz and above and reduces the gain of the VCA until the average level of the sibilance is reduced below the threshold determined by the DE-ESSER THRESHOLD control.

EFFECTS SEND and RECEIVE ports allow the signal prior to the output attenuator to be sent to another processing device. The processed signal is then summed back in with the main signal at the desired level using the EFFECTS RETURN control.

The GAIN REDUCTION meter consists of ten comparators arranged to produce a meter with a 0-25dB linear scale.

The PEAK OUTPUT LEVEL meter is an LED bargraph that monitors the output level of the 787A just prior to the balanced output stage. The meter is driven by a peak detector capable of reading the peak level of a 10-microsecond pulse with an accuracy of 0.5dB (typical) when compared to its reading on a steady-state tone. It thus provides a true peak-reading capability, rather than a quasi-peak capability like an EBU-standard PPM (peak program meter).

Unregulated voltage is supplied by three pairs of full wave diode rectifiers. ±15v and +5v regulated voltages are supplied by a pair of overrated 500mA "three-terminal" IC regulators. A discrete circuit supplies the regulated +48 volts.

2. Input Buffer

The signal enters the 787A in balanced form receiving modest RF suppression. It is then applied to a very low-noise opamp configured as a differential amplifier with a 0.5 gain. When both non-inverting and inverting inputs are driven by a source impedance which is small with respect to 40k (600Ω or less), the amplifier is essentially insensitive to signal components that appear equally on the non-inverting and inverting inputs (such as hum), and responds with full gain to the difference between the non-inverting and inverting inputs. It therefore serves as an "active transformer."

Since the INPUT ATTEN control is located after the opamp, the opamp will overload if its differential input exceeds approximately $+26 \, \text{dBu}$ ($0 \, \text{dBu} = 0.775 \, \text{V RMS}$; the dBm @ 600Ω scale on voltmeters can be read as if were calibrated in dBu).

Component-level description:

C1 and C2 shunt RF from the input leads to the chassis. Since these capacitors are not effective at VHF and higher frequencies, ferrite beads have been placed around the input and output leads to suppress such high-frequency RF. Although this RF suppression is modest, it should be adequate for the vast majority of installations.

The filtered signal is applied to opamp IC2a.

TECHNICAL DATA

3. Input Attenuator

A Multiplying Digital to Analog Converter (MDAC) controls the input gain digitally. The transconductance of the MDAC and the resistors connected to the inverting terminal of the opamp determines the voltage gain of this stage. No gain is available with jumper A in the +4dB position. Approximately 14dB is available in the -10dB setting.

Component-level description:

The IC1's internal resistor ladder is set by the 8-bit word written to its internal data latch. The word present on the data bus labelled DB0-DB7 is loaded into the MDAC when pins 12 and 13 of IC1 are clocked low. The resistor ladder of IC1 is in the feedback path of inverting amplifier IC5b, controlling gain. R3 and R4 are summing resistors, in series when jumper A is in the +4dBu position. R4 is shorted in the -10dBu position. The gain can be adjusted from 0dB to -30dB in the +4dBu position and from +14dB to -16dB in the -10dBu position.

When jumper B is in the MIC OPTION position, the MIC PRE-AMP signal is summed into IC5b through the internal resistor between pin 16 and pin 1 of IC1. The gain applied to the mic signal can be adjusted from +30dB to 0dB.

The range of INPUT ATTENuation is displayed on the front panel display as "+5dB" to "-25dB" for all jumper settings and input sources.

4. Voltage-controlled Amplifiers

The current-controlled gain block used in the 787A is a proprietary class-A voltage-controlled amplifier (VCA). It operates as a two-quadrant analog divider with gain *inversely* proportional to a current injected into a first gain-control port, and is cascaded with a two-quadrant analog multiplier with gain *directly* proportional to a current injected into a second gain-control port. For most gains, levels, and frequencies, total harmonic distortion (THD) is well under 0.1

A specially-graded Orban IC contains two matched, non-linear gain-control blocks with differential inputs and current outputs. Used alone, one such gain-control block would introduce considerable distortion. Therefore, the first of the two matched blocks is used as the feedback element for a separate opamp, and the second is driven by the pre-distorted output of that opamp. The gain of the VCA is therefore *inversely* proportional to the gain of the non-linear gain-control blocks. This enables the VCA to function as a two-quadrant analog divider.

If the VCA is not perfectly balanced, "thumps," due to control current feedthrough can appear at the output. These are eliminated by applying DC offset to the VCA's input.

The basic current-controlled gain in the compressor is *inversely* proportional to the control current generated by the compressor control circuitry. The gain is made proportional to a control voltage in dB by an exponential current converter.

Component-level description:

The first gain-control port is pin 6 of IC8; the second gain-control port is pin 3 of IC8. IC8 is the specially-graded Orban IC containing two matched non-linear gain-control blocks with differential inputs and current outputs. The separate opamp in the feedback loop is IC7.

The output of IC8 is first attenuated by R36, R35, C12, and then applied to the input of the feedback element IC8b at pin 9. The output of IC8 is pre-distorted as necessary to force the current output of IC8b to precisely and linearly cancel the audio input into the "virtual ground" summing junction of IC7. This same pre-distorted voltage is also connected to the input of IC8a at pin 16. Thus the output of IC8a at pin 13 is an undistorted current. This current is converted to a voltage in current-to-voltage converter IC6, R42, and C15. The output of IC6 at pin 1 is the output of the VCA.

The VCA behaves like a two-quadrant analog divider when the control current from Q2 is applied to the control port (pin 6) of IC8b. The gain-control current injected into this control port is developed by the compressor control circuitry.

The gain of IC8a is fixed by the current source which is set by R72 and IC18b. This current source is also the control current used by the DE-ESSER.

Second-harmonic distortion is introduced by differential offsets in either section of IC8. This distortion is canceled by applying a nulling voltage directly to the input of IC8a by means of resistor network R38, R39, and DIST NULL trimmer R37.

The "thumps" which can occur if the VCA is not perfectly balanced, are equivalent to multiplying the control current by DC. An adjustable DC offset is applied to the VCA input provided by R31 and THUMP NULL trimmer R30 for nulling this equivalent DC multiplication to zero.

C10, C11, R27, R28 provide frequency-compensation to prevent the VCA from oscillating supersonically.

The compressor control current is dB-linear. This voltage is transformed into a current *inversely* proportional to the desired compressor gain by exponential current converter IC20 and associated components.

IC19 and associated components form a log/antilog multiplier which multiplies the current flowing in R21 by the exponential of the voltage on the base of IC20 (pin 5). The current gain of the multiplier (and thus the output current of the exponential converter) increases as the voltage on the base of IC5 (pin 5) becomes more negative.

The current output of the log/antilog multiplier appears on the collector of IC20 (pin 3). Since it is the wrong polarity and level to correctly drive the control-current port of IC8b, it is applied to current inverter IC19b, Q2, R32, R33, C9. This circuit has a gain of 6.66x, and operates as follows:

A voltage proportional to the current output of IC20 (pin 3) is developed across R32 because of the feedback action of IC19b. C9 stabilizes IC19b against oscillations. Feedback forces IC19's (-) and (+) inputs to be at the same voltage. Thus, the same voltage that appears across R32 also appears across R33, and current flows in R33 in proportion to the ratio between the values of R32 and R33.

This current flows out of the (+) input line of IC19b into the emitter of Q2. Because Q2's base current is small compared to its emitter current, essentially the same current flows out of Q2's collector into the gain-control port of IC8b.

Since the base of Q2 is grounded, its emitter therefore sits at +0.6V. This forces both (+) and (-) inputs of IC19 to also sit at +0.6V, and ensures correct bias voltage for IC20's collector (pin 3).

CR2 protects Q2 from reverse base-emitter voltage which otherwise could cause junction breakdown and latch-up of the entire current-inverter circuit.

5. Equalizer

The three band equalizer consists of three stages of a state-variable topology. The switched resistor elements of multiplying Digital to Analog Converters (MDACs) allow microprocessor control of boost-cut, center frequency, and "Q" or bandwidth. The high and mid bands differ from the low band in that compensation capacitors C7 and C12 are used to correct phase characteristics to achieve maximum notching depth.

Component-level description:

The following component level description of the low band circuit can be readily extended to the other bands by analogy.

The LOW band consists of ICs 13-15 and ICs 1-4 with associated components. The state variable topology used provides a low-pass, high-pass, and band-pass output.

Pin 7, IC15 is the low-pass output. IC15b with MDAC IC3, C4, C25, and C26 is an integrator with gain adjustable with MDAC IC3.

The low-pass output is summed at IC13b by R3 with the input of the state variable to obtain the high-pass signal at pin 7 IC13b. The gain of the input signal set with MDAC IC1 determines the "Q", or bandwidth. MDAC IC4 with C2, C3, and C5 integrates the high-pass output to provide the band-pass output at pin 1 of IC 15.

The band-pass signal is summed at pin 6 IC14 with the input of the state variable and with an inversion of it's bandpass output. The gain of the inverted bandpass output is set with MDAC IC2 and IC13a determines the boost-cut characteristics at the output of the filter at Pin 7 IC14.

6. Compressor Control

The compressor is a feedback circuit: the gain-controlled output of the compressor is used to develop a gain-control signal that is applied to the compressor gain-control port of the VCA. This arrangement results in superior stability of characteristics with time and temperature, extremely low distortion, and optimized control-loop dynamic response.

The output of the opamp in the VCA is applied to a rectifier with threshold.

The rectifier feeds the compressor timing module, which contains proprietary circuitry that outputs a control voltage with dynamics appropriate to achieving natural-sounding control and very low modulation distortion. The output of the module can be wired in a logical "OR" circuit with other such modules to effect stereo tracking of an arbitrary number of channels.

The RELEASE TIME control allows a 50:1 variation in the basic release dynamics, which are determined by the timing module on the basis of the past history of the input. The release recovery proceeds at a constant rate (in dB/second) regardless of the absolute gain reduction.

A gating detector monitors the level of the 787A's input signal, and activates the gate if this level drops below a threshold set with the GATE THRESHOld control.

The GAIN REDUCTION meter consists of ten comparators with current regulators at their outputs. The comparators are arranged to produce a meter with a linear scale. The ten LEDs in the bargraph are connected in series.

Component-level description:

The output of IC7 in the VCA is applied to a rectifier with threshold in IC21b, a conventional full-wave rectifier. Attack times are determined by R67, R65. Any DC offsets at IC7's output are blocked by C13.

IC15b is a comparator that prevents the release module from being overdriven by the input signal. When the gain control voltage at TP3 reaches 11.8v, pin 2 of IC15b will go to -15 volts and pinch off FET Q3. This will prevent any further gain reduction from taking place until the gain reduction control voltage drops below 11.8 volts.

The output of the timing module is a low-impedance unidirectional voltage source, negative-going with increasing gain reduction (scale factor of approximately 0.4V/dB). 0V corresponds to 0dB gain reduction. Approximately -10V corresponds to the maximum available gain reduction (25dB).

The gain reduction voltage, which is dB-linear, is attenuated and inverted by IC32a, R135, and R136 such that +3V = 25dB gain reduction. The attenuated voltage is mixed with a 50 or 60Hz "dither" signal through CR29, R30, and C23 (connected to the power transformer secondary), and then applied to the input of LM3914 bargraph driver IC2.

The LM3914 bargraph consists of ten comparators with current regulators at their outputs. The comparators are arranged to produce a meter with a linear scale. The LM3914 applies current (through any one of pins 1 through 10) to the appropriate node to light the desired LEDs.

Q13 is used as a zener diode to reduce the supply voltage to the LM3914 so that it is within the chip's 25V maximum rating. R31 sets the current through the LED bargraph.

The LM3914 has an internal string of series resistors that provide reference voltages for its ten comparators. The bottom of this string is grounded at pin 4; the top of the string is provided with +3.00VDC from pin 1 of IC29a.

C1 bypasses the LM3914 power supply to prevent the LM3914 from oscillating.

The compressor release time is set by the DC voltage produced by IC27 and IC28b. IC27 scales the +15 volt reference voltage at pin 15 and is buffered by IC28b. This voltage is fed into the compressor module A1 at pin 8.

Under gated conditions (when the gating FET Q1 is turned off by pulling its gate towards +15 volts), the gain control voltage is forced to move slowly towards the voltage produced by divider R19 and R18. This voltage is then routed to the **timing module** through R20.

The gate is activated when the output of IC38a at pin 1 is pulled HIGH by R16, and is defeated when it is negative.

The gating circuit determines the threshold and response time of the compressor gate and noise gate.

IC33A and IC33B full wave rectify the signal from the input attenuator. The charge time constant at hold capacitor C34 is set by R108, and the discharge time is set by R107. C33 provides a low frequency roll-off. R107 sets a gain of 20dB.

IC35 and IC36A form a digitally-controlled reference voltage. The output of IC36A is a fraction of the +15 volt reference at pin 15, inverted. The magnitude of this reference voltage will depend on the control word written to MDAC IC35.

The reference voltage is scaled by R109 and R110 and compared to the rectified input signal at IC36B. The output of IC36B will go low to -15V when the rectified signal is greater than the reference at pin 5 of IC36B and is high (+15) otherwise. R111 and R112 provide hysteresis to prevent noise from re-triggering this comparator circuit.

The gate threshold circuit is common to the noise and compressor gate, although each gate has its own timing circuity.

The compressor gate time constants are set by R93, R99, and C31. When the signal at pin 10 of comparator IC38 reaches the 7.5 volts set by divider R98 and R96, pin 13 of IC38 goes low. This forces comparator IC38 pin 1 low which turns off FET Q1. Q1 off causes the control voltage at TP4 to advance towards -4 volts, set by divider R18 and R19. R97 provides hysteresis.

When the signal at pin 10 IC38d goes above 7.5 volts, pin 13 IC38d is pulled to 2 volts by R100 and R101. This forces IC38a pin 1 high turning Q1 on. Normal release will then occur.

The gate LED on the front panel is driven by IC37a which is triggered by the compressor gate detector IC38d.

The control current input of the second stage of the VCA is also used for the DE-ESSER and the NOISE GATE.

The de-esser control current flows from the collector of IC17a. A current identical to the de-esser control current flows from the collector of IC17b, since IC17a and IC17b are matched transistors. The current output of IC17b is inverted in current mirror IC17c-e, and injected into the junction of R40 and R41, where it develops a voltage. The voltage is amplified in both inverting and non-inverting modes by IC6a. When the wiper of R41 is at 50% rotation, then IC6a's inverting and non-inverting gains are equal, and no effect is produced at IC6as' output due to cancellation. Moving the wiper of R41 to either side of the null point permits introduction of sufficient control voltage into IC6a's output to cancel any feedthrough in IC8A, regardless of the feedthrough's polarity.

7. Noise Gate:

The time constants for the noise gate is set by R113, R114, and C32. When the signal at pin 8 of comparator IC38c reaches the 7.5 volts set by divider R115 and R116 at pin 9 the output of the comparator goes low. This forces the output of IC15c (pin 13) low which swamps the voltage from IC13a applied through R81. CR11 prevents the depth control voltage at pin 5 IC16b from going below -.7 volts.

IC12, 13a, and 16b with associated components determine the noise gate depth, attack time and release time. IC12 scales the reference voltage set by CR22 R151a and R151b to determine the noise gate depth. R81 and R82 with C19 will determine the rate at which the gate will attenuate the audio signal.

8. DE-ESSER

The DE-ESSER circuit detects sibilance in the region of 6kHz and above and will attenuate the output of the VCA until the sibilance is below the amount selected by the DE-ESSER THRESHOLD control.

Component-level description:

The VCA output (which includes the effect of IC6B, the de-esser gain control element) is applied to the de-esser control module, A2. This contains circuitry which detects the presence of sibilance and which outputs a current when sibilance levels exceed a level set by IC14, IC13b, R79, and R80, the de-esser THRESHOLD control circuit.

The output current of the de-esser control module is applied to CR7 and CR9, which charge C17 and C18 to approximately equal positive voltages. The release time of the circuit is determined by R75 which discharges C18. When C18 has been discharged sufficiently to overcome the turn-on voltage of CR8, C17 will also discharge. Since the voltage on C17 determines the amount of de-esser gain reduction, this recovery delay function provided by CR8 substantially aids in smoothing the de-esser control voltage and reduces dynamic distortion.

IC18b is a non-inverting voltage-to-current converter. When the de-esser control voltage (buffered by IC16a) is at ground, 9.1 volts set by CR22 appears across R72 because feedback holds IC18b's (+) and (-) inputs at the same voltage. This causes current to flow in R72, which flows in the emitter IC17a. Essentially the same amount of current flows out of IC17a collector to the control-current port of IC8a, thus determining the quiescent gain of IC8a.

When the de-esser gain control voltage becomes more positive, The voltage across R72 is decreased, thus reducing the control current into IC8a and reducing the gain of the VCA.

The DE-ESSER control voltage is OR'ed with the NOISE GATE control voltage at IC18b. Therefore, both circuits can operate at the same time, with the voltage of greater magnitude determining the amount of attenuation.

9. Effects Send and Receive:

EFFECTS SEND and RECEIVE ports allow the signal prior to the output attenuator to be sent to another processing device. The processed signal is summed back in with the main signal at the desired level.

Component-level description:

Pin 16 of connector P3 is the output of the compressor and equalizer stages. This signal is buffered by IC11a and isolated with R10 before being sent to the EFFECTS SEND output of TB1.

The EFFECTS RECEIVE input stage consists of a balanced opamp circuit IC11b and R12-13. DC blocking capacitors C6 and C7 feed the EFFECTS RECEIVE gain stage IC4, IC5a, R143, and R144. R143 and R144 allow this stage to have up to 14dB of gain depending on the control word written to IC4. The output of the EFFECTS RECEIVE is at pin 1 IC5.

10. PEAK OUTPUT LEVEL Metering

The peak-detecting PEAK OUTPUT LEVEL meter is an LED bargraph that monitors the output level of the 787A just prior to the balanced output stage. The meter is driven by a **peak detector** capable of reading the peak level of a 10-microsecond pulse with an accuracy of 0.5dB (typical) when compared to its reading on a steady-state tone. It thus provides a true peak-reading capability, rather than a quasi-peak capability like an EBU-standard PPM.

Component-level description:

The output of IC9 (pin 6) is applied to amplifier IC32b. The output of IC32b is rectified by an inverting **half-wave precision rectifier** IC30a and associated components. The output of the rectifier is summed (through R127) with its input to create a full-wave rectified signal at the (+) input of IC30b (pin 5).

IC30b operates as a dual-time constant **peak detector**. A DC voltage equal to the peak value of the rectified signal at pin 5 of IC30b is developed at the top of C35, which is charged by IC30b pin 7 through diode-connected transistor Q5. IC29b buffers this voltage and provides feedback to IC30b's pin 6, "telling" IC30b how to charge C35, C36 so that the peak value of the waveform on IC30b's pin 5 is accurately followed.

To achieve the very fast response desired, the peak-holding capacitors C35 and C36 are relatively small. To achieve a sufficiently slow recovery time with a practical value resistor (R131 = 22meg), R131 is bootstrapped to the output of IC29b through R132. R133 introduces enough DC offset to produce approximately 0.5V across R130 and R131 at all times. This multiplies the effective value of R130 and R131 by about 30, and slows down the recovery time as desired.

The output of **peak detector** IC30a (pin 1) is applied to LM3916 bargraph driver IC1 (DP board). Other than the fact that this IC provides a VU (rather than a linear) scale, its operation is identical to the operation of the LM3914 used in the IC2 (DP board) socket (see above).

11. Overload Indicator

The output of each main-signal-path amplifier in the 787A is connected to an overload bus. This overload bus will light the front panel OVERLOAD LED when the signal at any point in the 787A is within 1dB of clipping.

Component-level description:

The output of each main-signal-path amplifier in the 787A is connected to a pair of diodes. One diode is connected to a +10 volt bus (created by R87, R88); and the other diode is connected to a -10 volt bus (created by R83, R84). If the instantaneous output of any amplifier exceeds ±10 volts, then the appropriate diode will conduct and couple a pulse onto one of the busses, which are of relatively high impedance. Positive-going overload pulses are fed into transistor inverter Q6 and appear at Q6's collector amplified and inverted so that they are negative going. Thus any overload appears at Q6's collector as a negative-going pulse. This pulse is coupled through C29 to IC34 and associated circuitry, connected as a one-shot multivibrator.

Ordinarily, IC34 is held off (pin 6 low) because R89 holds IC34's inverting input at a higher voltage than voltage divider R90, R92 holds its non-inverting input. A negative-going pulse transmitted through C29 pulls IC32's inverting input down, thus briefly switching IC32's output high. This in turn pulls IC32's non-inverting input high through R91, C30, and latches IC32's output high until C30 can discharge through R91, R90, R92, which normally takes 200 milliseconds. While IC34's output is high, the OVERLOAD lamp is illuminated through R102 and Q7, connected as a zener diode. Thus very fast overloads are "timestretched" and can be easily seen.

Under continuous overload conditions, it is normal for the overload LED to flash on and off.

12. Power Supply

Unregulated voltage for the analog circuitry is supplied by two pairs of **full-wave diode rectifiers**. The nominal unregulated voltage is ± 22 volts DC at rated line voltage. This will vary widely with line voltage variations. Regulator dropout will occur if the unregulated voltage falls below about ± 17.8 volts.

Unregulated voltage for the digital circuitry is supplied by two pairs of full-wave diode rectifiers. The nominal unregulated voltage is ± 10 volts DC at rated line voltage. This will vary widely with line voltage variations. Regulator dropout will occur if the unregulated voltage falls below about ± 7 volts.

This unregulated voltage is also used to power the front panel LEDs and displays.

Unregulated voltage for the phantom power is supplied by a **full-wave diode rectifier**. The nominal unregulated voltage is +70 volts DC at rated line voltage. This will vary widely with line voltage variations and load to the +48 volt source

Regulator dropout will occur if the unregulated voltage falls below about +55 volts.

Regulated voltages for the +15 volts and +5 volts are supplied by a pair of 500mA "three-terminal" IC regulators.

The +48 volt phantom power is supplied by a discreet voltage regulator.

Component-level description:

The two pairs of **full-wave diode rectifiers** that supply unregulated voltage are located in package BR1, BR2, and BR3. The rectifier pairs drive energy storage capacitors C9 C6, C7, and C8. The power transformer T1 can be strapped for either 115-volt or 230-volt operation (the two sections of the primary are paralleled for 115-volt operation and connected in series for 230-volt operation).

Four of the ICs which supply regulated voltages are "three-terminal" IC regulators IC1, IC2, IC3, IC17. These regulators are frequency-compensated by C12, C14, C15, C18 at their outputs to prevent high-frequency oscillations. Small 0.1mF/25V ceramic capacitors bypass the power busses to ground locally throughout the board to prevent signal-carrying ICs from oscillating due to excessive power-lead inductance.

(If replaced, C12, C14, C18, and C15 must be replaced by low-inductance aluminum electrolytic capacitors only — see "Power supply problems" on 5-3.)

The +48 volt phantom power is regulated by Darlington pass transistor Q1. The base of Q1 is referenced by a 51 volt zener diode CR13 which is biased by R32. The emitter of Q1 has a 1.2 volt forward drop across it when a load is applied. Current limiting protection is provided by Q2 and R33. When the output current sourced by Q1 causes a .6 volt drop across R33, Q2 will turn on and shut Q1 off by shunting its base to emitter voltage.

13. Microphone Pre-amp

The microphone pre-amp is a transformer/IC opamp hybrid. The transformer provides 20dB of gain and the opamp provides 16dB. A jumper selectable pad is provided to attenuate the input signal 20dB. +48 volt phantom power is also jumper selectable.

Component-level description:

The microphone pre-amp input signal is applied to input transformer T1.

T1's secondary winding is loaded by R6. R7 raises the DC impedance IC1 sees at its input to an appropriate level to avoid excessive open loop gain.

C2 and C3 provide RFI suppression. C14 compensates IC1's open loop gain for stability. R9, R10, and C4 set the gain and frequency response of IC1. R8 decouples IC1's output (pin 6) and C9, C10, and C11 are DC blocking capacitors. C11 bypasses C9, C10 to ensure highest audio quality.

The +48 volt phantom power is filtered by R1, C1, and C12. R2a and R2b are matched to increase the common mode rejection.

Parts List

Parts are listed by ASSEMBLY, then by TYPE, then by REFERENCE DESIGNATOR. Widely used common parts are not listed; such parts are described generally below (examine the part to determine exact value). See the following assembly drawings for locations of components.

SIGNAL DIODES, if not listed by reference designator in the following parts list, are:

Orban part number 22101-000, Fairchild (FSC) part number 1N4148, also available from many other vendors. This is a silicon, small-signal diode with ultra-fast recovery and high conductance. It may be replaced with 1N914 (BAY-61 in Europe).

(BV: 75V min. @ $I_r = 5\mu A$ I_r : 25nA max. @ $V_r = 20V$ V_f : 1.0V max. @ I_f = 100mA t_{rr} : 4ns max.) See Miscellaneous list for **ZENER DIODES** (reference designator VRxx).

RESISTORS should only be replaced with the same style and with the *exact* value marked on the resistor body. If the value marking is not legible, consult the schematic or the factory. Performance and stability will be compromised if you do not use exact replacements. Unless listed by reference designator in the following parts list, resistors are:

Metal film resistors which have conformally-coated bodies, and are identified by five color bands or a printed value. They are rated at ½ watt @ 70°C, ±1%, with a temperature coefficient of 100 PPM/°C. Orban part numbers 20038-xxx through 20045-xxx, USA Military Specification MIL-R-10509 Style RN55D. Manufactured by R-Ohm (CRB-1/4FX), TRW/IRC, Beyschlag, Dale, Corning, and Matsushita.

Carbon film resistors which have conformally-coated bodies, and are identified by four color bands. They are rated at $^{1}/_{4}$ watt @ 70° C, $\pm 5\%$. Orban part numbers 20001-xxx, Manufactured by R-Ohm (R-25), Piher, Beyschlag, Dale, Phillips, Spectrol, and Matsushita.

Carbon composition resistors which have molded phenolic bodies, and are identified by four color bands. The 0.090×0.250 inch $(2.3 \times 6.4 \text{ mm})$ size is rated at $^{1}\!/_{2}$ watt, and the 0.140×0.375 inch $(3.6 \times 9.5 \text{ mm})$ size is rated at $^{1}\!/_{2}$ watt, both $\pm 5\%$ @ 70° C. Orban part numbers 2001x-xxx, USA Military Specification MIL-R-11 Style RC-07 ($^{1}\!/_{4}$ watt) or RC-20 ($^{1}\!/_{2}$ watt). Manufactured by Allen-Bradley, TRW/IRC, and Matsushita.

Cermet trimmer resistors which have $\frac{3}{8}$ -inch (9 mm) square bodies, and are identified by printing on their sides. They are rated at $\frac{1}{2}$ watt @ 70° C, $\pm 10\%$, with a temperature coefficient of 100 PPM/ $^{\circ}$ C. Orban part numbers 20510-xxx and 20511-xxx. Manufactured by Beckman (72P, 68W- series), Spectrol, and Matsushita.

Obtaining spare parts:

Special or subtle characteristics of certain components are exploited to produce an elegant design at a reasonable cost. It is therefore unwise to make substitutions for listed parts. Consult the factory if the listing of a part includes the note "selected" or "realignment required."

Orban normally maintains an inventory of tested, exact replacement parts that can be supplied quickly at nominal cost. Standardized spare parts kits are also available. When ordering parts from the factory, please have available the following information about the parts you want:

> Orban part number Reference designator (e.g., C3, R78, IC14) Brief description of part Model, serial, and "M" (if any) number of unit — see rear-panel label

To facilitate future maintenance, parts for this unit have been chosen from the catalogs of well-known manufacturers whenever possible. Most of these manufacturers have extensive worldwide distribution and may be contacted through their local offices. Their USA headquarters addresses are given on page 6-39.

REF DES	DESCRIPTION	ORBAN P/N	VEN (1)	VENDOR P/N	ALTERNATE VENDORS (1)	NOTES
	1					
MAIN UNIT F	NAL ASSEMBLY					
Miscellar	negus					
B1	Coin Cell, Lithium; 3V	28041-000	DUR	DL2032	GE	
Fi	Fuse, 3AG, Slo-Blo, 1/2A	28004-150	LFE ORB	313.500	BUS	
NONE NONE	Transformer, Power; 39VCT, 10VCT, 23VA Filter, Line, 3 Amp	55012-000 28015-000	COR	3EF1	MANY	
NONE	Line Cord, CEE	28102-002	BEL	17500	MANY	
NONE	Sub Assy, 10 Position Barrier Strip	40064-000	ORB			
NONE	Sub Assy, 10 Position Barrier Strip	40067-000	ORB			
NONE NONE	Sub Assy, Heatsink Regulator Sub Assy, XLR Connector, Input	40068-001 40065-000	ORB ORB			
NONE	Sub Assy, XLR Connector, Output	40066-000	ORB			
Switches	•					
Switches						
NONE	Switch, Slide, Mains voltage selector	26140-000	SW	EPSI-SLI		
PCB ANALOG	ASSEMBLY [AG]					
Capacito	<u>rs</u>					
C1,2	Mica, 500V, +1/2pF -1/2pF; 22pF	21017-022	CD	CD15-CD220D03	SAN	
C3	Met. Polyester, 100V, 10%; 1.0uF	21441-510	WIM	MKS-4100V5.1.0	WES, SIE	
C4-7	Alum., Radial, 50V, -20% +100%; 47uF	21208-647	SPR	502D 476G050CD1C	PAN	
C8	Mica, 500V, 5%; 100pF	21020-110	CD	CD15~FD101J03	SAN	
C9 C10,11	Mica, 500V, +1/2pF -1/2pF; 10pF Mica, 500V, 5%; 150pF	21017-010 21020-115	CD CB	CD15-CD100D03 CD15-FB151J03	SAN San	
C12	Mica, 500V, +1/2pF -1/2pF; 5pF	21020-113	CD	CD15-CD050D03	SAN	
C13	Alum., Radial, 63V, -20% +100%; 4.7uF	21209-547	SPR	502D 475G063BB1C	PAN	
C14	Tantalum, 35V, 10%; 0.22uF	21307-422	SPR	196D 224X9035HA1	MANY	
C15	Mica, 500V, +1/2pF -1/2pF; 47pF	21017-047	CD	CD15-CD470D03	SAN	
C16	Not used					
C17,18	Met. Palyester, 100V, 10%; 0.1uF	21441-410	WIM	MKS-4100V5.0.1	WES, SIE	
C19	Met. Polyester, 100V, 10%; 0.047uF	21441-347	WES	160C 473K250	SIE	
C20,21	Alum., Radial, 25V, -20% +100%; 100uF	21206-710	PAN	ECE-A1EV101S		
C22,23	Monolythic Ceramic, 50V, 20%; 0.1uF	21123-410	SPR	1C25 Z5U104M050B	KEM	
C24,25	Alum, Radial, 25V, -20% +100%; 100uF	21206-710	PAN	ECE-A1EV101S	VEM	
C26,27 C28,29	Monolythic Ceramic, 50V, 20%; 0.1uF Ceramic Bisc, 50V, +80% -20%; 0.005uF	21123-410 21108-250	SPR	1C25 Z5U104M050B CK-502	KEM	
020,27	Ceramic Bisc, 30V, 400% -20%; 0:003ur	21100-230	CKL	UK-302	WIID	

C30

C33

C31.32

- (1) See last page for abbreviations
- (2) No Alternate Vendors known at publication

Ceramic Disc, 25V, 20%; 0.15uF

Met. Polyester, 100V, 10%; 0.047uF

Met. Polyester, 100V, 10%; 0.01uF

- (3) Actual part is specially selected from part listed, consult Factory
- (4) Realignment may be required if replaced, see Circuit Description and/or Alignment Instructions

UK25-154

WES 160C 103K630

160C 473K250

21106-415

21441-347

21441-310

MUR

SIE

SIE, WIM

SPECIFICATIONS AND SOURCES FOR REPLACEMENT PARTS

787A MIC PROCESSOR
Main Unit Final Assy, PCB Analog
Assy: Capacitors

				· · · · · · · · · · · · · · · · · · ·		
REF DES	DESCRIPTION	ORBAN P/N	VEN (1)	VENDOR P/N	ALTERNATE VENDORS (1)	NOTES
C34	Met. Polyester, 100V, 10%; 0.047uF	21441-347	WES	160C 473K250	SIE	
C35,36	Met. Polyester, 100V, 10%; 0.01uF	21441-310	WES	160C 473K230	SIE, WIM	
C37	Mica, 500V, 5%; 1000pF	21024-210	CD	CD19-FD102J03	SAN	
C38	Met. Polyester, 100V, 10%; 0.047uF	21441-347	WES	160C 473K250	SIE	
C39-64	Monolythic Ceramic, 50V, 20%; 0.1uF	21123-410	SPR	1C25 Z5U104M050B	KEM	
C65	Met. Polyester, 100V, 10%; 1.0uF	21441-510	WIM	MKS-4100V5.1.0	WES, SIE	
C66, 67	Alum., Radial, 25V, -20% +100%; 100uF	21206-710		ECE-A1EV101S	WLS, SIL	
Diodes					•	
CR5	Not used					
CR15	Not used					
CR22	Diode, Zener, 1W; 9.1V	22003-091	TOM	1N4739	MANY	
Integrat	ed Circuits					
IC1	Digital, Multiplying DAC	24714-302	AD	AD7524JN		
IC2	Linear, Dual Opamp	24207-202	SIG	NE5532N	TI, EXR	
103	Not used					•
IC4	Digital, Multiplying DAC	24714-302	ΑD	AD7524JN		
105	Linear, Dual Opamp	24209-202	NAT	LF412CN		
106	Linear, Dual Opamp	24206-202	ΤI	TL072CP	MOT	
IC7	Linear, Single Opamp	24014-202	SIG	NE5534N	TI	
108	Linear, Dual Opamp	24208-302	RCA	CA3280A		
109	Linear, Single Opamp	24017-202	NAT	LF411CN		
IC10	Not used					
IC11	Linear, Dual Opamp	24207-202	SIG	NE5532N	TI,EXR	
IC12	Digital, Multiplying DAC	24714-302	AD	AD7524JN		
IC13 .	Linear, Dual Opamp	24209-202	NAT	LF412CN		
IC14	Digital, Multiplying DAC	24714-302	AD	AD7524JN		
IC15	Quad Comparator	24710-302	NAT	LM339		
IC16	Linear, Dual Opamp	24209-202	NAT	LF412CN		
IC17	Multiple Discrete, TR. Array	24406-302	RCA	CA3096AE		
IC18	Linear, Dual Opamp	24206-202	ΤI	TL072CP	MOT	
1019	Linear, Dual Opamp	24209-202	NAT	LF412CN		
IC20	Multiple Discrete, TR, Array	24406-302	RCA	CA3096AE		
1021	Linear, Dual Opamp	24209-202	NAT	LF412CN		
IC22-25	Digital, 3 To 8 Line Decoder	24556-302	NAT	MM74HCT138N	T I	
1026	Digital, Flip-Flop	24561-302	NAT	MM74HCT374N		
IC27	Digital, Multiplying DAC	24714-302	ΑD	AD7524JN		
IC28-30	Linear, Dual Opamp	24209-202	NAT	LF412CN		
1031	Quad Comparator	24710-302	NAT	LM339		
1032,33	Linear, Dual Opamp	24209-202	NAT	LF412CN		
IC34	Linear, Single Opamp	24002-202	TI	UA741CN	RAY	
1035	Digital, Multiplying DAC	24714-302	AD	AD7524JN		
1036	Linear, Dual Opamp	24209-202	NAT	LF412CN		
1037	Linear, Dual Opamp	24203-202	MOT	MC145BCP1	TI,RCA	
IC38	Quad Comparator	24710-302	NAT	LM339		

- (1) See last page for abbreviations
 (2) No Alternate Vendors known at publication
 (3) Actual part is specially selected from part listed, consult Factory
- (4) Realignment may be required if replaced, see Circuit Description and/or Alignment Instructions

SPECIFICATIONS AND SOURCES FOR REPLACEMENT PARTS

787A MIC PROCESSOR PCB Analog Assy: Capacitors, Diodes, ICs

REF DESCRIPTION	r		ı ı			F -	
Module Assy, Compressor	I I					ALTERNATE	
### Add suffix printed on part	DES	DESCRIPTION	ORBAN P/N	(1)	VENDOR P/N	VENDORS (1)	NOTES
### Add suffix printed on part			· · · · · · · · · · · · · · · · · · ·			· · · · · · · · · · · · · · · · · · ·	<u> </u>
A2	<u>Modules</u>						
A2	Δ1	Module Assy. Compressor	21125-000	ממח			wadd m
Resistors Resistor Set, NF; 20.5K 28521-008 ORB 20% CW Log							· · · · · · · · · · · · · · · · · · ·
Resistors Resistor Set MF; 20.5K 28521-008 ORB 20X CW Log							
R153a,b			31100 001 11	UND			-nau surrix printeu on part
Transistor Transistor JET7/P 23407-101 NAT J174 S1L	Resistors						
R45	R153a, b	Resistor Set, MF; 20.5K	28521-008	ORB			3
Q1 Transistor, JFET/P 23407-101 NAT J174 SIL Q2 Transistor, Signal, PNP 23001-101 MOT 2N4125 FSC Q3,4 Transistor, JFET/N 23406-101 NAT J113 SIL Q5-8 Transistor, Signal, NPN 23202-101 MOT 2N4400 FSC PCB DIGITAL & PWR SUPPLY ASSY [DG] Capacitors C1 Mica, 500V, +1/2pF -1/2pF; 30pF 21017-030 CD CD15-CD300D03 SAN C2 Hica, 500V, 5%; 100pF 21020-110 CD CD15-FD101303 SAN C2- Hica, 500V, 5%; 100pF 21020-110 CD CD15-FD101303 SAN C3-S Alum., Radial, 62V, -20X +100X; 1uF 21209-510 SPR 502D 10550638BIC PAN C6-8 Alum., Axial, 40V, -10X +100X; 1000uF 21224-810 SIE B41010-1000-40 PAN C7- Alum., Axial, 100V, -20X +20X; 100uF 21226-710 ME 3074HH0101100JPB PAN C10 Not used C11 Honolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEH C12 Alum., Radial, 25V, -20X +100X; 100uF 21226-710 PAN ECE-ALEVIOLS C14, 1S Alum., Radial, 25V, -20X +100X; 100uF 21226-710 PAN ECE-ALEVIOLS C14, 1S Alum., Radial, 25V, -20X +00X; 100uF 21226-710 PAN ECE-ALEVIOLS C14, 1S Alum., Radial, 25V, -20X +100X; 100uF 21206-710 PAN ECE-ALEVIOLS C16, 17 Honolythic Ceramic, 50V, 20X; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C118 Alum., Radial, 25V, -20X +100X; 100uF 21206-710 PAN ECE-ALEVIOLS C18 Alum., Radial, 25V, -20X +100X; 100uF 21206-710 PAN ECE-ALEVIOLS C19 Monolythic Ceramic, 50V, 20X; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C118 Alum., Radial, 25V, -20X +100X; 100uF 21206-710 PAN ECE-ALEVIOLS C19 Monolythic Ceramic, 50V, 20X; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C10 Monolythic Ceramic, 50V, 20X; 0.1uF 2123-410 SPR 1C25 Z5U104M050B KEM C119 Monolythic Ceramic, 50V, 20X; 0.1uF 2123-410 SPR 1C25 Z5U104M050B KEM C120 Alum., Radial, 25V, -20X +100X; 100uF 21244-310 WES 160C 103K630 SIE, WIH C22 Het, Polyester, 100V, 10X; 0.0uF 21441-310 WES 160C 103K630 SIE, WIH C22 Het, Polyester, 100V, 10X; 0.0uF 21441-310 WES 160C 103K630 SIE, WIH C23 Het, Polyester, 100V, 10X; 0.0uF 21441-310 WES 160C 103K630 SIE, WIH C24 Het, Polyester, 100V, 10X; 0.0uF 21441-310 WES 160C 103K630 SIE, WIH C25 Het, Polyester, 100V, 10X; 0.0uF 21441-310 WES 160C 103K	R45	Pot, Single, 10%; 50K (5020)					
Q1 Transistor, JFET/P 23407-101 NAT J174 SIL Q2 Transistor, Signal, PNP 23001-101 MOT 2N4125 FSC Q3,4 Transistor, JFET/N 23406-101 NAT J13 SIL Q5-8 Transistor, JFET/N 23406-101 NAT J13 SIL Q5-8 Transistor, Signal, NPN 23202-101 MOT 2N4400 FSC CD	Transisto	ra					•
Q2 Transistor, Signal, PNP 23001-101 MDT 2M4125 FSC Q3.4 Transistor, JFET/N 23406-101 NAT J113 S1L Q5-8 Transistor, Signal, NPN 23202-101 MDT ZN4400 FSC PSC PSC PSC PSC PSC PSC PSC PSC PSC P	11 411313101	<u> </u>					
Q2 Transistor, Signal, PNP 23001-101 MDT 2M4125 FSC Q3.4 Transistor, JFET/N 23406-101 NAT J113 S1L Q5-8 Transistor, Signal, NPN 23202-101 MDT ZN4400 FSC PSC PSC PSC PSC PSC PSC PSC PSC PSC P	Q1	Transistor, JFET/P	23407-101	NAT	J174	SIL	
Q3,4							
Capacitors Cap		Transistor, JFET/N	23406-101	NAT			
C1 Mica, 500V, +1/2pF -1/2pF; 30pF 21017-030 CD CD15-CD300D03 SAN C2 Mica, 500V, 5%; 100pF 21020-110 CD CD15-FD101J03 SAN C3-8 Alum., Radial, 63V, -20% +100%; 10F 21224-810 SIE 841010-1000-40 PAN C6-8 Alum., Axial, 40V, -10% +100%; 1000F 21224-810 SIE 841010-1000-40 PAN C7 Alum., Axial, 100V, -20% +20%; 100uF 21226-710 ME 3074HH101T100JPB PAN C10 Not used C11 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M50B KEM C12 Alum., Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-ALEV101S C13 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M50B KEM C14, 15 Alum., Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-ALEV101S C16, 17 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M50B KEM C16, 17 Monolythic Ceramic, 50V, 20%; 0.1uF 2123-410 SPR 1C25 Z5U104M50B KEM C16, 17 Monolythic Ceramic, 50V, 20%; 0.1uF 2123-410 SPR 1C25 Z5U104M50B KEM C18 Alum., Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-ALEV101S C16, 17 Monolythic Ceramic, 50V, 20%; 0.1uF 2123-410 SPR 1C25 Z5U104M50B KEM C18 Alum., Radial, 63V, -20% +100%; 100uF 21206-710 PAN ECE-ALEV101S C19 Monolythic Ceramic, 50V, 20%; 0.1uF 2123-410 SPR 1C25 Z5U104M50B KEM C20 Alum., Radial, 63V, -20% +100%; 33uF 21209-633 SPR 502D 336G063CC1C PAN C21 Met. Polyester, 100V, 10%; 0.1uF 21441-310 WES 160C 103K630 SIE, WIM C22 Met. Polyester, 100V, 10%; 0.1uF 21441-310 WES 160C 103K630 SIE, WIM C23 Met. Polyester, 100V, 10%; 0.0uF 21441-310 WES 160C 103K630 SIE, WIM	Q5-8	Transistor, Signal, NPN	23202-101	MOT	2N4400	FSC	
C1 Mica, 500V, +1/2pF -1/2pF; 30pF 21017-030 CD CD15-CD300D03 SAN C2 Mica, 500V, 5%; 100pF 21020-110 CD CD15-FD101J03 SAN C3-8 Alum., Radial, 63V, -20% +100%; 10F 21224-810 SIE 841010-1000-40 PAN C9 Alum., Axial, 100V, -20% +20%; 100uF 21224-810 SIE 841010-1000-40 PAN C9 Alum., Axial, 100V, -20% +20%; 100uF 21226-710 ME 3074HH101T100JPB PAN C10 Not used C11 Honolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C12 Alum., Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-ALEV101S C13 Honolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C14, 15 Alum., Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-ALEV101S C16, 17 Honolythic Ceramic, 50V, 20%; 0.1uF 2123-410 SPR 1C25 Z5U104M050B KEM C18 Alum., Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-ALEV101S C16, 17 Honolythic Ceramic, 50V, 20%; 0.1uF 2123-410 SPR 1C25 Z5U104M050B KEM C18 Alum., Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-ALEV101S C16, 17 Honolythic Ceramic, 50V, 20%; 0.1uF 2123-410 SPR 1C25 Z5U104M050B KEM C18 Alum., Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-ALEV101S C19 Honolythic Ceramic, 50V, 20%; 0.1uF 2123-410 SPR 1C25 Z5U104M050B KEM C20 Alum., Radial, 63V, -20% +100%; 100uF 21206-710 PAN ECE-ALEV101S C19 Honolythic Ceramic, 50V, 20%; 0.1uF 2123-410 SPR 1C25 Z5U104M050B KEM C20 Alum., Radial, 63V, -20% +100%; 100uF 21441-310 WES 160C 103K630 SIE, WIM C22 Met. Polyester, 100V, 10%; 0.1uF 21441-310 WES 160C 103K630 SIE, WIM C22 Met. Polyester, 100V, 10%; 0.1uF 21441-310 WES 160C 103K630 SIE, WIM							
C1 Mica, 500V, +1/2pF -1/2pF; 30pF 21017-030 CD CD15-CD300D03 SAN C2 Mica, 500V, 5%; 100pF 21020-110 CD CD15-FD101J03 SAN C3-S Alum., Radial, 63V, -20% +100%; 10F 21224-810 SIE 841010-1000-40 PAN C6-8 Alum., Axial, 40V, -10% +100%; 1000F 21224-810 SIE 841010-1000-40 PAN C7 Alum., Axial, 100V, -20% +20%; 1000F 21226-710 ME 3074HH101T100JPB PAN C10 Not used	PCD DICITAL (DMD CHDDIV ACCV INCI					
C1 Mica, 500V, +1/2pF -1/2pF; 30pF 21017-030 CD CD15-CD300D03 SAN C2 Mica, 500V, 5%; 100pF 21020-110 CD CD15-FD101J03 SAN C3-5 Alum., Radial, 63V, -20% +100%; 1uF 21209-510 SPR 502D 105C063BBIC PAN C6-8 Alum., Axial, 40V, -10% +100%; 1000uF 21224-810 SIE 841010-1000-40 PAN C9 Alum., Axial, 100V, -20% +20%; 100uF 21226-710 ME 3074HH101T100JPB PAN C10 Not used C10 Not used C11 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104H050B KEM C12 Alum., Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECC-AIEV101S C13 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104H050B KEM C14,15 Alum., Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECC-AIEV101S C16,17 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104H050B KEM C18 Alum., Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECC-AIEV101S C16,17 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104H050B KEM C19 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104H050B KEM C19 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104H050B KEM C20 Alum., Radial, 63V, -20% +100%; 33uF 21209-633 SPR 502D 336G063CC1C PAN Met. Polyester, 100V, 10%; 0.01uF 21441-310 WES 160C 103K630 SIE, WIM MES.4100VS.0.1 WES, SIE C23 Met. Polyester, 100V, 10%; 0.01uF 21441-310 WES 160C 103K630 SIE, WIM	FUB DIGITAL C	Y FWR SUFFLI MSSI (BG)					
C1 Mica, 500V, +1/2pF -1/2pF; 30pF 21017-030 CD CD15-CD300D03 SAN C2 Mica, 500V, 5%; 100pF 21020-110 CD CD15-FD101J03 SAN C3-5 Alum., Radial, 63V, -20% +100%; 1uF 21209-510 SPR 502D 105G063BBIC PAN C6-8 Alum., Axial, 40V, -10% +100%; 1000uF 21224-810 SIE 841010-1000-40 PAN C9 Alum., Axial, 100V, -20% +20%; 100uF 21226-710 ME 3074HH101T100JPB PAN C10 Not used C11 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C12 Alum., Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-AIEV101S C13 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C14,15 Alum., Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-AIEV101S C16,17 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C18 Alum., Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-AIEV101S C19 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C20 Alum., Radial, 63V, -20% +100%; 33uF 21209-633 SPR 502D 336G063CC1C PAN C20 Alum., Radial, 63V, -20% +100%; 33uF 21209-633 SPR 502D 336G063CC1C PAN C21 Met. Polyester, 100V, 10%; 0.1uF 21441-310 WES 160C 103K630 SIE, WIM C22 Met. Polyester, 100V, 10%; 0.1uF 21441-310 WES 160C 103K630 SIE, WIM C23 Met. Polyester, 100V, 10%; 0.1uF 21441-310 WES 160C 103K630 SIE, WIM	Capacitor	5					
C2 Mica, 500V, 5%; 100pF 21020-110 CD CD15-FD101J03 SAN C3-5 Alum., Radial, 63V, -20% +100%; 1uF 21209-510 SPR 502D 105G063BBIC PAN C6-8 Alum., Axial, 40V, -10% +100%; 100uF 21224-810 SIE B41010-1000-40 PAN C9 Alum., Axial, 100V, -20% +20%; 100uF 21226-710 ME 3074HH101T100JPB PAN C10 Not used C11 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C12 Alum., Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-A1EV101S C13 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C14,15 Alum., Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-A1EV101S C16,17 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C18 Alum., Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-A1EV101S C19 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C20 Alum., Radial, 63V, -20% +100%; 33uF 21209-633 SPR 502D 336G063CC1C PAN C21 Met. Polyester, 100V, 10%; 0.1uF 21441-310 WES 160C 103K630 SIE,WIM C22 Met. Polyester, 100V, 10%; 0.01uF 21441-310 WES 160C 103K630 SIE,WIM C23 Met. Polyester, 100V, 10%; 0.01uF 21441-310 WES 160C 103K630 SIE,WIM		_					
C3-5 Alum., Radial, 63V, -20X +100X; 1uF 21207-510 SPR 502D 105G063BBIC PAN C6-8 Alum., Axial, 40V, -10X +100X; 1000uF 21224-810 SIE B41010-1000-40 PAN C9 Alum., Axial, 100V, -20X +20X; 100uF 21226-710 ME 3074HH101T100JPB PAN C10 Not used		Mica, 500V, +1/2pF -1/2pF; 30pF	21017-030	CD	CD15-CD300D03	SAN	
C6-8 Alum., Axial, 40V, -10% +100%; 1000uF 21224-810 SIE B41010-1000-40 PAN Alum., Axial, 100V, -20% +20%; 100uF 21226-710 ME 3074HH101T100JPB PAN C10 Not used C11 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C12 Alum., Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-A1EV101S C13 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C14,15 Alum., Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-A1EV101S C16,17 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C18 Alum., Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-A1EV101S C19 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C20 Alum., Radial, 63V, -20% +100%; 33uF 21209-633 SPR 502D 336G063CC1C PAN Met. Polyester, 100V, 10%; 0.01uF 21441-310 WES 160C 103K630 SIE, WIM C22 Met. Polyester, 100V, 10%; 0.01uF 21441-310 WES 160C 103K630 SIE, WIM C23 Met. Polyester, 100V, 10%; 0.01uF 21441-310 WES 160C 103K630 SIE, WIM			21020-110	CD	CD15-FD101J03	SAN	
C9 Alum, Axial, 100V, -20% +20%; 100uF 21226-710 ME 3074HH101T100JPB PAN C10 Not used C11 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C12 Alum, Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-ALEV101S C13 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C14,15 Alum, Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-ALEV101S C16,17 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C18 Alum, Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-ALEV101S C19 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C20 Alum, Radial, 63V, -20% +100%; 33uF 2123-410 SPR 1C25 Z5U104M050B KEM C21 Met. Polyester, 100V, 10%; 0.01uF 21441-310 WES 160C 103K630 SIE, WIM C22 Met. Polyester, 100V, 10%; 0.01uF 21441-310 WES 160C 103K630 SIE, WIM C23 Met. Polyester, 100V, 10%; 0.01uF 21441-310 WES 160C 103K630 SIE, WIM			21209-510	SPR	502D 105G063BBIC	PAN	
C10 Not used C11 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C12 Alum., Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-A1EV101S C13 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C14,15 Alum., Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-A1EV101S C16,17 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C18 Alum., Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-A1EV101S C19 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C20 Alum., Radial, 63V, -20% +100%; 33uF 21209-633 SPR 502D 336G063CC1C PAN C21 Met. Polyester, 100V, 10%; 0.0uF 21441-310 WES 160C 103K630 SIE,WIM C22 Met. Polyester, 100V, 10%; 0.0uF 21441-410 WIM MKS-4100V5.0.1 WES,SIE C23 Met. Polyester, 100V, 10%; 0.0uF 21441-310 WES 160C 103K630 SIE,WIM							
C11 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C12 Alum., Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-A1EV101S C13 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C14,15 Alum., Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-A1EV101S C16,17 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C18 Alum., Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-A1EV101S C19 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C20 Alum., Radial, 63V, -20% +100%; 33uF 21209-633 SPR 502D 336G063CC1C PAN C21 Met. Polyester, 100V, 10%; 0.1uF 21441-310 WES 160C 103K630 SIE,WIM C22 Met. Polyester, 100V, 10%; 0.1uF 21441-410 WIM MKS-4100V5.0.1 WES,SIE C23 Met. Polyester, 100V, 10%; 0.0luF 21441-310 WES 160C 103K630 SIE,WIM				ME	3074HH101T100JPB	PAN	
C12 Alum., Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-ALEV101S C13 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 25U104M050B KEM C14,15 Alum., Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-ALEV101S C16,17 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 25U104M050B KEM C18 Alum., Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-ALEV101S C19 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 25U104M050B KEM C20 Alum., Radial, 63V, -20% +100%; 33uF 21209-633 SPR 502D 336G063CC1C PAN C21 Met. Polyester, 100V, 10%; 0.01uF 21441-310 WES 160C 103K630 SIE,WIM C22 Met. Polyester, 100V, 10%; 0.01uF 21441-410 WIM MKS-4100V5.0.1 WES,SIE C23 Met. Polyester, 100V, 10%; 0.01uF 21441-310 WES 160C 103K630 SIE,WIM				con	ACOE DEULAAMATAD	W.F.W	
C13 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 25U104M050B KEM C14,15 Alum., Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-A1EV101S C16,17 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 25U104M050B KEM C18 Alum., Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-A1EV101S C19 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 25U104M050B KEM C20 Alum., Radial, 63V, -20% +100%; 33uF 21209-633 SPR 502D 336G063CC1C PAN C21 Met. Polyester, 100V, 10%; 0.01uF 21441-310 WES 160C 103K630 SIE,WIM C22 Met. Polyester, 100V, 10%; 0.01uF 21441-410 WIM MKS-4100V5.0.1 WES,SIE C23 Met. Polyester, 100V, 10%; 0.01uF 21441-310 WES 160C 103K630 SIE,WIM						KEM	
C14,15 Alum, Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-ALEV101S C16,17 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C18 Alum, Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-ALEV101S C19 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C20 Alum, Radial, 63V, -20% +100%; 33uF 21209-633 SPR 502D 336G063CC1C PAN C21 Met. Polyester, 100V, 10%; 0.01uF 21441-310 WES 160C 103K630 SIE,WIM C22 Met. Polyester, 100V, 10%; 0.01uF 21441-410 WIM MKS-4100V5.0.1 WES,SIE C23 Met. Polyester, 100V, 10%; 0.01uF 21441-310 WES 160C 103K630 SIE,WIM						VEM	
C16,17 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C18 Alum., Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-A1EV101S C19 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C20 Alum., Radial, 63V, -20% +100%; 33uF 21209-633 SPR 502D 336G063CC1C PAN C21 Met. Polyester, 100V, 10%; 0.01uF 21441-310 WES 160C 103K630 SIE,WIM C22 Met. Polyester, 100V, 10%; 0.1uF 21441-410 WIM MKS-4100V5.0.1 WES,SIE C23 Met. Polyester, 100V, 10%; 0.01uF 21441-310 WES 160C 103K630 SIE,WIM						KEN	
C18 Alum., Radial, 25V, -20% +100%; 100uF 21206-710 PAN ECE-ALEV101S C19 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 25V104M050B KEM C20 Alum., Radial, 63V, -20% +100%; 33uF 21209-633 SPR 502D 336G063CC1C PAN C21 Met. Polyester, 100V, 10%; 0.01uF 21441-310 WES 160C 103K630 SIE,WIM C22 Met. Polyester, 100V, 10%; 0.1uF 21441-410 WIM MKS-4100V5.0.1 WES,SIE C23 Met. Polyester, 100V, 10%; 0.01uF 21441-310 WES 160C 103K630 SIE,WIM		and the second s				KEM	
C19 Monolythic Ceramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM C20 Alum., Radial, 63V, -20% +100%; 33uF 21209-633 SPR 502D 336G063CC1C PAN C21 Met. Polyester, 100V, 10%; 0.01uF 21441-310 WES 160C 103K630 SIE, WIM C22 Met. Polyester, 100V, 10%; 0.1uF 21441-410 WIM MKS-4100V5.0.1 WES, SIE C23 Met. Polyester, 100V, 10%; 0.01uF 21441-310 WES 160C 103K630 SIE, WIM							
C20 Alum., Radial, 63V, -20% +100%; 33uF 21209-633 SPR 502D 336G063CC1C PAN C21 Met. Polyester, 100V, 10%; 0.01uF 21441-310 WES 160C 103K630 SIE,WIM C22 Met. Polyester, 100V, 10%; 0.1uF 21441-410 WIM MKS-4100V5.0.1 WES,SIE C23 Met. Polyester, 100V, 10%; 0.01uF 21441-310 WES 160C 103K630 SIE,WIM	C19					KEM	
C21 Met. Polyester, 100V, 10%; 0.01uF 21441-310 WES 160C 103K630 SIE,WIM C22 Met. Polyester, 100V, 10%; 0.1uF 21441-410 WIM MKS-4100V5.0.1 WES,SIE C23 Met. Polyester, 100V, 10%; 0.01uF 21441-310 WES 160C 103K630 SIE,WIM		Alum., Radial, 63V, -20% +100%; 33uF					
C22 Met. Polyester, 100V, 10%; 0.1uF 21441-410 WIM MKS-4100V5.0.1 WES,SIE C23 Met. Polyester, 100V, 10%; 0.01uF 21441-310 WES 160C 103K630 SIE,WIM			21441-310	WES			
The same same same same same same same sam						WES, SIE	
L24-33 Monolythic Geramic, 50V, 20%; 0.1uF 21123-410 SPR 1C25 Z5U104M050B KEM		· · · · · · · · · · · · · · · · · · ·					
	024-33	monolythic Ceramic, 50V, 20%; 0.1uF	21123-410	SPR	1C25 Z5U104M050B	KEM	
<u>Diodes</u>	Diodes						
BR1-3 Diode, Bridge, 200V, 1A 22301-000 VARO VE-27 G1	BR1-3	Diode, Bridge, 200V. 1A	22301-000	UADO	UF - 27	C1	
CRI Diode, Voltage Reference 22081-112 NAT LM385 MOT							
CR11,12 Diode, Signal, Hot Carrier 22102-001 HP HP5082-2800 MANY							
CR13 Diode, Zener, 1W; 51V 22004-510 NOT 1N4757A MANY							
CR14 Diode, Rectifier, 400V, 1A 22201-400 MOT 1N4004 MANY	CR14						
							

- (1) See last page for abbreviations(2) No Alternate Vendors known at publication
- (3) Actual part is specially selected from part listed, consult Factory
- (4) Realignment may be required if replaced, see Circuit Description and/or Alignment Instructions

SPECIFICATIONS AND SOURCES FOR REPLACEMENT PARTS

787A MIC PROCESSOR

PCB Analog Assy: Modules, Resistors, Transistors; PCB Digital & Pwr Supply Assy: Capacitors, Diodes

REF DES	DESCRIPTION	ORBAN P/N	VEN (1)	VENDOR P/N	ALTERNATE VENDORS (1)
Integ	rated Circuits				
ICi	Digital, NAND Gate	24557-302	RCA	CD54/74HCT32	
102	Digital, Hex Inverter	24551-302	NAT	74HCT04N	TI
103	Digital, Dual Flip-Flop	24552-302	NAT	MM74HCT74N	TI
IC4	Digital, CPU, 280	24804-302	TOS	TMPZ84C00AP	
105,6	Digital, 3 To 8 Line Decoder	24556-302	NAT	MM74HCT138N	T I
IC7	Digital, RAM	24806-302	TOS	TC5564PL-20	
108	Digital, Quad 2-Input NAND	24559-302	RCA	74HCT132E	T I
109	Digital, AND Gate	24560-302	NAT	74HCT08	
IC10	Digital, PROM	44002-000	ORB		
IC11	Digital, Transceiver	2455B-302	NAT	MM74HCT245N	RCA
IC12	Digital, Flip-Flop	24561-302	NAT	MM74HCT374N	
IC13	Quad Comparator	24710-302	NAT	LM339	
1C14	Digital, Flip-Flop	24561-302	NAT	MM74HCT374N	
IC15	Digital, Buffer	24554-302		MM74HCT244N	TI
IC16	Digital, Flip-Flop	24561-302	NAT	MM74HCT374N	
IC17	D.C. Regulator, 5V Positive	24307-901	NAT	LM78M05C	TI, MOT
Misce	llaneous				
NONE	Battery Holder, Coin Cell	28031-000	KEY	106	
P2	Cable Assy, Flat, 40 Pin, 5 inches	42008-050	ORB		
Y1	Crystal; 8 MHz	28051-001	MID	C2150	
Resis	tors				
R4-7	Resistor Network, SIP; 100K	20221-101	BEK	L10-1C104	
R21	Resistor Network, SIP; 100K	20221-101	BEK	L10-1C104	
R34	Resistor Network, SIP; 100K	20221-101	BEK	L10-1C104	
Switc	hes				
51	Switch, MOM., Gray; SPST	26301-005	SCH	D6-02-05	
Trans	istors				
Qi	Transistor, Power, NPN; TO-220	23604-201	TI	TIP122	RCA
Q2,3	Transistor, Signal, NPN	23202-101	MOT	2N4400	FSC

- (1) See last page for abbreviations
 (2) No Alternate Vendors known at publication
 (3) Actual part is specially selected from part listed, consult Factory
- Realignment may be required if replaced, see Circuit Description and/or Alignment Instructions

SPECIFICATIONS AND SOURCES FOR REPLACEMENT PARTS

NOTES

787A MIC PROCESSOR PCB Digital & Pwr Supply Assy: ICs, Misc., Resistors, Switches, Transistors

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REF			VEN		ALTERNATE	
DES	DESCRIPTION	ORBAN P/N	(1)	VENDOR P/N	VENDORS (1)	NOTES
		I	1		<u> </u>	
DOD DIEDLAY	ACCEMBLY EDD3					
PCB DISPLAY	ASSEMBLY [DP]					
Capacito	· S					
<u> </u>	_					
C1	Alum., Radial, 63V, -20% +100%; 2.2uF	21209-522	SPR	502D 225G063BB1C	PAN	
C2-6	Alum., Radial, 25V, -20% +100%; 100uF	21206-710	PAN	ECE-A1EV101S	*****	
C7-12	Monolythic Ceramic, 50V, 20%; 0.1uF	21123-410	SPR	1C25 Z5U104M050B	KEM	
C13	Alum, Radial, 63V, -20% +100%; 2,2uF	21209-522 21209-510	SPR SPR	502D 225G063BB1C 502D 105G063BBIC	PAN PAN	
C14 C15	Alum., Radial, 63V, -20% +100%; 1uF Monolythic Ceramic, 50V, 20%; 0.1uF	21123-410	SPR	1C25 Z5U104M050B	KEM	
CIJ	indidiyinic beramic; oov, zow, ortal	21120 410	31 K	1020 800104110000		
Integrat	ed Circuits					
	mental and a mental and a	04740 060	11 A T			
ICi	Digital, Display Briver	24713-302 24712-302	NAT NAT	LM3916 LM3914		
1C2 1C3	Digital, Display Driver Digital, Flip-Flop	24712-302	NAT	MM74HCT374N		
103	Digital, LED Driver	24410-302	MOT	ULN2803		
105	Digital, Flip-Flop	24561-302	NAT	MM74HCT374N		
106	Digital, LED Driver	24410-302	MOT	ULN2803		
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<u>LEDs</u>				•		
D1-3	LED Display, 0-9, Red	25402-000	HР	5082-7613	GI	
D4	LED Display, +/- 1	25401-000	HP	5082-7616		
DS1	LED, Red	25106-003	HP	HLMP-1300	GI	
DS2	LED, Green	25106-002	HP	HLMP-1503	GI	
DS3-8	LED, Red	25106-003	HP	HLMP-1300	GI	
DS9	LED Array, 6-Green, 3-Yellow, 1-Red	25151-000	ORB			
DS10	Not used	7510/ 007	115	HLMP-1300	GI	
DS11,12	LED, Red	25106-003 25106-002	HP HP	HLMP-1503	GI	
DS13 DS14-19	LED, Green LED, Red	25106-002	HP	HLMP-1300	GI	
DS20	LED Array, 9-Yellow, 1-Red	25152-000	ORB	110111 1000	.	
2020	220 m ay, 7 10110m 1 1 11-1					
<u>Miscella</u>	neous					
D4	Cable Ages Flat 40 Bin 4 inches	42008-060	ORB			
P1	Cable Assy, Flat, 40 Pin, 6 inches	72000-000	UKB			
Switches						
Si	Switch, MOM.; SPST	26302-001	SCH	D6-01-01		
51 52-5	Switch, MOM., With Red LED; SPDT	26323-011	SCH			
52 3 56	Switch, MOM.; SPDT	26322-010	SCH	SEAUo.A.0101		
S7-17	Switch, MOM., With Red LED; SPDT	26323-011	SCH	SEAUo.A.0102R		
518	Switch, MOM.; SPDT	26322-010	SCH	SEAU0.A.0101		
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- (1) See last page for abbreviations
 (2) No Alternate Vendors known at publication
 (3) Actual part is specially selected from part listed, consult Factory
- (4) Realignment may be required if replaced, see Circuit Description and/or Alignment Instructions

SPECIFICATIONS AND SOURCES FOR REPLACEMENT PARTS

787A MIC PROCESSOR PCB Display Assy: Capacitors, ICs LEDs Misc., Switches

REF DES	DESCRIPTION	ORBAN P/N	VEN (1)	VENDOR P/N	ALTERNATE VENDORS (1)	NOTES				
Transistors										
Q1	Transistor, Signal, NPN	23202-101	TOM	2N4400	FSC					
Q2 Q3	Transistor, Signal, PNP Transistor, Signal, NPN	23002-101 23202-101	MOT	2N4402 2N4400	FSC FSC					
Q4-11	Transistor, Signal, PNP	23002-101	MOT	2N4400 2N4402	FSC					
Q12,13	Transistor, Signal, NPN	23202-101		2N4400	FSC					
PCB EQUALIZE	R ASSEMBLY [EQ]									
<u>Capacitor</u>	<u>'5</u>									
Ci	Met. Polyester, 100V, 10%; 1.0uF	21441-510	WIM	MKS-4100V5.1.0	WES, SIE					
C2	Polypropylene, 50V, 1%; 0.01uF	21701-310	NOB	CQ15P1H103FPP	WES					
C3	Mica, 500V, 1%; 1000pF	21022-210	CD	CD19-FD102F03	SAN					
C4	Polypropylene, 50V, 1%; 0.01uF	21701-310	NOB	CQ15P1H103FPP	WES					
C5	Mica, 500V, 1%; 1000pF	21022-210	CD	CD19-FD102F03	SAN					
C 6 C 7	Alum., Radial, 50V, -20% +100%; 47uF Polypropylene, Trimmer; 2-10pF	21208-647 21802-000	SPR ME	502B 476G050CD1C	PAN					
C8	Alum., Radial, 50V, -20% +100%; 47uF	21208-647	SPR	2807C00210MJ02F 502D 476G050CD1C	PAN					
C9,10	Mica, 500V, 1%; 1000pF	21022-210	CD	CD19-FD102F03	SAN					
C11	Mica, 500V, +1/2pF -1/2pF; 22pF	21017-022	CD	CD15-CD220D03	SAN					
C12	Polypropylene, Trimmer; 2-10pF	21802-000	ME	2807C00210MJ02F						
C13	Mica, 500V, +1/2pF -1/2pF; 22pF	21017-022	CD	CD15-CD220D03	SAN					
C14-17	Mica, 500V, 1%; 1000pF	21022-210	CD	CD19-FD102F03	SAN					
C18	Mica, 500V, +1/2pF -1/2pF; 22pF	21017-022	CD	CD15-CD220D03	SAN					
C19-21	Alum., Radial, 25V, -20% +100%; 100uF	21206-710	PAN	ECE-A1EV101S						
C22-24	Monolythic Ceramic, 50V, 20%; 0.1uF	21123-410	SPR	1C25 Z5U104M050B	KEM					
C25,26	Mica, 500V, 1%; 1000pF	21022-210	CD	CD19-FD102F03	SAN					
C27-38	Monolythic Ceramic, 50V, 20%; 0.1uF	21123-410	SPR	1C25 25U104M050B	KEM					
Integrate	ed Circuits									
IC1	See selected components									
IC2	Digital, Multiplying DAC	24714-302	AD	AB7524JN						
IC3-5	See selected components									
106	Digital, Multiplying DAC	24714-302	AD	AD7524JN						
IC7-9	See selected components									
IC10	Digital, Multiplying DAC	24714-302	AD	AD7524JN						
IC11,12	See selected components	0.007 0.0								
IC13,14 IC15	Linear, Dual Opamp	24207-202	SIG	NE5532N	TI, EXR					
IC15	Linear, Dual Opamp Linear, Dual Opamp	24209-202 24207-202		LF412CN NE5532N	TI, EXR					
IC18, 17	Linear, Dual Opamp	24211-202	MOT	MC34082P	111 EAR					
1020	Linear, Dual Opamp	24209-202		LF412CN						
1021	Linear, Dual Opamp	24211-202		MC34082P						
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- See last page for abbreviations No Alternate Vendors known at publication
- (3) Actual part is specially selected from part listed, consult Factory
- (4) Realignment may be required if replaced, see Circuit Description and/or Alignment Instructions

SPECIFICATIONS AND SOURCES FOR REPLACEMENT PARTS

787A MIC PROCESSOR

PCB Display Assy: Transistors; PCB Equalizer Assy: Capacitors, ICs

REF DES	DESCRIPTION	ORBAN P/N	VEN (1)	VENDOR P/N	ALTERNATE VENDORS (1)	NOTES
			···			
PCB REMOTE I	NTERFACE ASSEMBLY [RI]					
Capacitor	<u>s</u>					
C1,2	Monolythic Ceramic, 50V, 20%; 0.1uF	21123-410	SPR	1C25 Z5U104M050B	KEM	
C3	Alum., Radial, 25V, -20% +100%; 100uF	21206-710	PAN	ECE-A1EV101S	KLII	
C4	Monolythic Ceramic, 50V, 20%; 0.1uF	21123-410	SPR	1C25 Z5U104M050B	KEM	
C5	Alum., Radial, 25V, -20% +100%; 100uF	21206-710		ECE-A1EV101S		
60	Monolythic Ceramic, 50V, 20%; 0.1uF	21123-410		1C25 Z5U104M050B	KEM	
C7,8	Ceramic Disc, 25V, 20%; 0.01uF	21106-310		UK25-103	MUR, SPR	
C9,10	Ceramic Disc, 1KV, 10%; 0.001uF	21112-210	CRL	DD-102	MUR	
C11-13	Ceramic Disc, 25V, 20%; 0.01uF	21106-310	CRL	UK25-103	MUR, SPR	
C14,15	Ceramic Disc, 1KV, 10%; 0.001uF	21112-210	CRL	DD-102	MUR	
C16	Ceramic Disc, 25V, 20%; 0.01uF	21106-310	CRL	UK25-103	MUR, SPR	
<u>Diodes</u>						
CR1	Diode, Rectifier, 400V, 1A	22201-400	MOT	1N4004	MANY	
Integrate	d Circuits					
IC1	Digital, NAND Gate	24557-302	RCA	CD54/74HCT32		
102	Digital, Quad 2-Input NAND	24559-302	RCA	74HCT132E	TI	
103	Digital, Dual Flip-Flop	24552-302	NAT	MM74HCT74N	TI	
104	Digital, Buffer	24554-302	NAT	MM74HCT244N	ŤÍ	
105	Digital, Hex Inverter	24601-302	TI	SN7406	•	
106	D.C. Regulator, 15V Positive	24304-901	NAT	LM78M15UC	TI, MOT	
	-					
Miscellar	<u>neous</u>					
NONE	Cable Assy, Flat, 26 Pin, 8 inches	42007-080	ORB			
PCB RS-232 /	ASSEMBLY (RS)					
	· - ••					
Capacito	<u>`\$</u>					
C1	Monolythic Ceramic, 50V, 20%; 0.1uF	21123-410	SPR	1C25 Z5U104M050B	KEM	
C2	Alum., Radial, 25V, -20% +100%; 100uF	21206-710	PAN	ECE-A1EV101S		
C3,4	Monolythic Ceramic, 50V, 20%; 0.1uF	21123-410	SPR	1C25 Z5U104M050B	KEM	
C5	Alum., Radial, 25V, -20% +100%; 100uF	21206-710	PAN	ECE-A1EV101S		
C6	Monolythic Ceramic, 50V, 20%; 0.1uF	21123-410	SPR	1C25 Z5U104M050B	KEM	
C7	Alum, Radial, 25V, -20% +100%; 100uF	21206-710	PAN	ECE-A1EV101S		
C8	Monolythic Ceramic, 50V, 20%; 0.1uF	21123-410	SPR	1C25 Z5U104M050B	KEM	
C9	Mica, 500V, 5%; 100pF	21020-110	CD	CD15-FB101J03	SAN	
C10	Mica, 500V, +1/2pF -1/2pF; 33pF	21017-033	CD	CD15-CD330D03	SAN	
C11-14	Monolythic Ceramic, 50V, 20%; 0.1uF	21123-410	SPR	1C25 25U104M050B	KEM	
						·

- (1) See last page for abbreviations
 (2) No Alternate Vendors known at publication
 (3) Actual part is specially selected from part listed, consult Factory
- Realignment may be required if replaced, see Circuit Description and/or Alignment Instructions

SPECIFICATIONS AND SOURCES FOR REPLACEMENT PARTS

787A MIC PROCESSOR PCB Remote Interface Assy; PCB RS-232 Assy: Capacitors

				· · · · · · · · · · · · · · · · · · ·	·	
REF			VEN		ALTERNATE	
DES	DESCRIPTION	ORBAN P/N	(1)	VENDOR P/N	VENDORS (1)	NOTES
			-			
Miscella	neous					
	B.1. A	45007 440				
P2	Cable Assy, Flat, 26 Pin, 6 inches	42007-060	ORB			Main unit only
P2	Cable Assy, Flat, 26 Pin, 3 inches	42007-030	ORB			Slave unit only
Resistor	<u>'5</u>					
R1	Resistor Network, 8 POS.; 20K	20201-501	חדע	698-3-R20KD		
R2	See selected components	20201-301	DEK	070-3-K2VKD		
R5,6	See selected components					
R8	Resistor Network, 8 POS.; 20K	20201-501	RFK	698-3-R20KD		
R9	See selected components			uu		
R12, 13	See selected components					
R15	Resistor Network, 8 POS.; 20K	20201-501	BEK	698-3-R20KD		
R16	See selected components					
R19,20	See selected components					
Selected	I Components					
	· 					
IC1/R2	Matched Set, IC/Resistor	40075-000	ORB			3
IC3/R6	Matched Set, IC/Resistor	40075-000	ORB			3
IC4/R5	Matched Set, IC/Resistor	40075-000	ORB			3 3
IC5/R9 IC7/R13	Matched Set, IC/Resistor Matched Set, IC/Resistor	40075-000 40075-000	ORB ORB			3 3
IC8/R12	Matched Set, IC/Resistor	40075-000	ORB			3
IC9/R12	Matched Set, IC/Resistor	40075-000	ORB			3
IC11/R20	Matched Set, IC/Resistor	40075-000	ORB			3
IC12/R19	Matched Set, IC/Resistor	40075-000	ORB			3
PCB MIC OPT	TION ASSEMBLY (MC)					
Capacito	ors					
C1	Met. Polyester, 100V, 10%; 0.1uF	21441-410	MIW		WES, SIE	
C2, 3	Mica, 500V, +1/2pF -1/2pF; 33pF	21017-033	CD	CD15-CD330D03	SAN	
C4	Mica, 500V, 1%; 160pF	21018-116	CD	CD15-FD161F03	SAN	
C5 C6	Alum., Radial, 25V, -20% +100%; 100uF Monolythic Ceramic, 50V, 20%; 0.1uF	21206-710 21123-410	PAN SPR	ECE-A1EV101S 1C25 Z5U104M050B	KEM	
C7	Alum., Radial, 25V, -20% +100%; 100uF	21206-710	PAN	ECE-A1EV101S	KEII	
C8	Monolythic Ceramic, 50V, 20%; 0.1uF	21123-410	SPR	1C25 Z5U104M050B	KEM	
C9,10	Alum., Radial, 50V, -20% +100%; 47uF	21208-647	SPR	502D 476G050CD1C	PAN	
C11	Met. Polyester, 100V, 10%; 1.0uF	21441-510	WIM	MKS-4100V5,1.0	WES, SIE	
C12	Alum., Radial, 63V, -20% +100%; 22uF	21209-622	SPR	502B 226G063CC1C	PAN	
C13	Not used					
C14	Mica, 500V, +1/2pF -1/2pF; 22pF	21017-022	CD	CD15-CD220D03	SAN	
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- (1) See last page for abbreviations
- (2) No Alternate Vendors known at publication
- (3) Actual part is specially selected from part listed, consult Factory
- Realignment may be required if replaced, see Circuit Description and/or Alignment Instructions

SPECIFICATIONS AND SOURCES FOR REPLACEMENT PARTS

787A MIC PROCESSOR

PCB RS-232 Assy: Misc., Resistors, Selected Components; PCB Mic Option Assy: Capacitors

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REF DES	DESCRIPTION	Orban P/N	VEN	VENDOR P/N	ALTERNATE VENDORS (1)	NOTES
					1	
Integrate	ed Circuits					
101	Linear, Single Opamp	24014-202	SIG	NE5534N	TI	
Miscellar	neous					
T1	Transformer	29108-000	JEN	JE-115K-E		
Resistors	<u>i</u>					
R2a, b	Resistor Set, MF; 6.81K	28521-023	ORB			3
·	·					
PCB MIDI OPT	TION ASSEMBLY (MD)					
Capacitor	<u>'5</u>					
C1	Alum., Radial, 25V, -20% +100%; 100uF	21206-710	PAN	ECE-A1EV101S		
C2,3	Monolythic Ceramic, 50V, 20%; 0.1uF	21123-410		1C25 Z5U104M050B	KEM	
n						
<u>Diodes</u>						
CR1	Diode, Rectifier, 400V, 1A	22201-400	TOM	1N4004	MANY	
Integrate	ed Circuits					
ICI	Digital, Microprocessor, 280, SIO/O	24803-302	TOS	TMPZ84C40P		
IC2	Digital, NAND Gate	24557-302	RCA			
103	Digital, Hex Inverter	24551-302	NAT	74HCT04N	ŢI	
IC4	Digital, Hex Inverter	24601-302	T I	SN7406		
105	Optocoupler	25005-302	HP	6N138	GI	
106	Digital, Microprocessor, 280	24807-302	TOS	TMPZ84C30P		
107	Digital, Dual Flip-Flop	24552-302	NAI	MM74HCT74N	TI	
Miscella	neous					
P1	Cable Assy, Flat, 26 Pin, 8 inches	42007-080	ORB			
D00 D10 D10	DIAN AGGENTALY CDD3					
FUR KIL DISI	PLAY ASSEMBLY [DB]					
LEDs						
81,2	LED Display, 0-9, Red	25402-000	НР	5082-7613	GI	

- (1) See last page for abbreviations(2) No Alternate Vendors known at publication
- (3) Actual part is specially selected from part listed, consult Factory
- Realignment may be required if replaced, see Circuit Description and/or Alignment Instructions

SPECIFICATIONS AND SOURCES FOR REPLACEMENT PARTS

787A MIC PROCESSOR
PCB Mic Option Assy: ICs, Misc.,
Resistors; PCB MIDI Option Assy; PCB R/C Display Assy

REF DES	DESCRIPTION	ORBAN P/N	VEN (1)	VENDOR P/N	ALTERNATE VENDORS (1)	NOTES		
PCB R/C MAIN	PCB R/C MAIN ASSEMBLY [MB]							
Capacitor	<u>Capacitors</u>							
C1,2	Ceramic Disc, 1KV, 10%; 0.001uF	21112-210	CRL	DD-102	MUR			
C3-7	Monolythic Ceramic, 50V, 20%; 0.1uF	21123-410		1C25 Z5U104M050B	KEM			
C8,9	Ceramic Disc, 1KV, 10%; 0.001uF	21112-210		DD-102	MUR			
C10 C11	Alum., Radial, 25V, -20% +100%; 100uF Monolythic Ceramic, 50V, 20%; 0.1uF	21206-710 21123-410		ECE-A1EV101S 1C25 25U104M050B	KEM			
Diodes	,,							
plodes								
CR1-6	Diode, Rectifier, 400V, 1A	22201-400	TOM	1N4004	MANY			
Integrate	ed Circuits							
IC1	Digital, Up-Counter	24508-302	RCA	CD4520BE		٧		
102,3	Digital, Dual Flip-Flop	24502-302		CD4013BE				
IC4	Digital, Driver	24563-302		CD4511BC	RCA			
IC5	Digital, Up-Counter	24508-302	RCA	CD4520BE				
109	Digital, Quad 2-Input NAND	24509-302	RCA	CD4093BE				
IC7	Digital, Hex Inverter	24505-302		CD4069UBE	SIG			
1 C 8	Digital, 1-in-4 Decoder	24506-302		CD4555BE	SIG			
109	Digital, 8 Channel Analog Multiplexer	24530-302		CD4051BC	RCA			
1010,11	Digital, Driver	24563-302		CD4511BC	RCA			
IC12	Digital, Dual Flip-Flop	24502-302		CD4013BE	551			
IC13 IC14	Digital, Encoder	24529-302		CD4532BCN	RCA			
1014 1015	Digital, Quad 2-Input NAND Digital, Dual Flip-Flop	24509-302 24502-302		CD4093BE CD4013BE				
Transistors								
Q 1	Transistor, Signal, NPN	23202-101	TOM	2N4400	FSC			
PCB R/C SWITCH ASSEMBLY [SB]								
Capacitors								
C1-4		21112-210	CDI	DD-102	MUR ·			
	Ceramic Disc, 1KV, 10%; 0.001uF	21112-210	LKL	PR-105	луп			
Switches								
51-3	Switch, MOM., With Red LED; SPDT	26323-011	SCH	SEAUo.A.0102R				
S4	Switch, MOM.; SPDT	26322-010	SCH	SEAUo.A.0101				

- (1) See last page for abbreviations
 (2) No Alternate Vendors known at publication
 (3) Actual part is specially selected from part listed, consult Factory
- Realignment may be required if replaced, see Circuit Description and/or Alignment Instructions

SPECIFICATIONS AND SOURCES FOR REPLACEMENT PARTS

787A MIC PROCESSOR PCB R/C Main Assy; PCB R/C Switch Assy

REF DES	DESCRIPTION	ORBAN P/N	VEN (1)	VENDOR P/N	ALTERNATE VENDORS (1)	NOTES		
PCB REMOTE	NTERFACE ASSEMBLY [R1]							
<u>Capacitors</u>								
C1,2 C3	Monolythic Ceramic, 50V, 20%; 0.1uF Alum., Radial, 25V, -20% +100%; 100uF	21123-410 21206-710	SPR PAN	1C25 Z5U104M050B ECE-A1EV101S	KEM			
C4	Monolythic Ceramic, 50V, 20%; 0.1uF	21123-410	SPR	1C25 Z5U104M050B	KEM			
C5	Alum, Radial, 25V, -20% +100%; 100uF	21206-710	PAN	ECE-A1EV101S				
63	Monolythic Ceramic, 50V, 20%; 0.1uF	21123-410	SPR	1C25 Z5U104M050B	KEM			
C7,8	Ceramic Disc, 25V, 20%; 0.01uF	21106-310	CRL	UK25-103	MUR, SPR			
C9,10	Ceramic Disc, 1KV, 10%; 0.001uF	21112-210	CRL	DD-102	MUR			
C11-13	Ceramic Disc, 25V, 20%; 0.01uF	21106-310	CRL	UK25-103	MUR, SPR			
C14,15	Ceramic Disc, 1KV, 10%; 0.001uF	21112-210	CRL	DD-102	MUR			
C16	Ceramic Disc, 25V, 20%; 0.01uF	21106-310	CRL	UK25-103	MUR, SPR			
<u>Diodes</u>								
CR1	Diode, Rectifier, 400V, 1A	22201-400	MOT	1N4004	MANY			
Integrate	Integrated Circuits							
101	Digital, NAND Gate	24557-302	RCA	CD54/74HCT32				
IC2	Digital, Quad 2-Input NAND	24559-302	RCA	74HCT132E	TI			
103	Digital, Dual Flip-Flop	24552-302	NAT	MM74HCT74N	TI			
IC4	Digital, Buffer	24554-302	NAT	MM74HCT244N	TI			
105	Digital, Hex Inverter	24601-302	TI	SN7406				
IC6	B.C. Regulator, 15V Positive	24304-901	NAT	LM78M15UC	TI, MOT			
Miscellaneous								
NONE	Cable Assy, Flat, 26 Pin, 8 inches	42007-080	ORB					
DOD DO 000	ACCEMBLY FREE							
PCB RS-232 ASSEMBLY [RS]								
<u>Capacitors</u>								
C1	Monolythic Ceramic, 50V, 20%; 0.1uF	21123-410	SPR	1C25 Z5U104M050B	KEM			
C2	Alum., Radial, 25V, -20% +100%; 100uF	21206-710	PAN	ECE-A1EV101S				
C3,4	Monolythic Ceramic, 50V, 20%; 0.1uF	21123-410	SPR	1C25 Z5U104M050B	KEM			
C5	Alum., Radial, 25V, -20% +100%; 100uF	21206-710	PAN	ECE-ALEVIOLS				
63	Monolythic Ceramic, 50V, 20%; 0.1uF	21123-410	SPR	1C25 Z5U104M050B	KEM			
C7	Alum., Radial, 25V, -20% +100%; 100uF	21206-710	PAN	ECE-A1EV101S	1/FW			
C8	Monolythic Ceramic, 50V, 20%; 0.1uF	21123-410	SPR	1C25 Z5U104M050B	KEM			
C9 C10	Mica, 500V, 5%; 100pF	21020-110	CD	CD15-FD101J03	SAN			
C11-14	Mica, 500V, +1/2pF -1/2pF; 33pF Monolythic Ceramic, 50V, 20%; 0.1uF	21017-033 21123-410	CD SPR	CD15-CD330D03 1C25 Z5U104M050B	SAN KEM			
VAL AT HORSELF THE DECEMBER OVER EVAL VIEW EXTENSIVE OF TOTAL BOUTSTHOOD BEH								
								

- (1) See last page for abbreviations
 (2) No Alternate Vendors known at publication
 (3) Actual part is specially selected from part listed, consult Factory
- (4) Realignment may be required if replaced, see Circuit Description and/or Alignment Instructions

SPECIFICATIONS AND SOURCES FOR REPLACEMENT PARTS

787A MIC PROCESSOR PCB Remote Interface Assy; PCB RS-232 Assy: Capacitors

REF DES	DESCRIPTION	ORBAN P/N	VEN (1)	VENDOR P/N	ALTERNATE VENDORS (1)	NOTES	
Integrat	Integrated Circuits						
IC1 IC2 IC3 IC4 IC5	Digital, Hex Inverter Digital, Dual Flip-Flop Digital, Quad Line Receiver Digital, Quad Line Driver Digital, NAND Gate	24551-302 24552-302 24662-302 24661-302 24557-302	NAT NAT NAT RCA	74HCTO4N MM74HCT74N DS14C89A DS14C88N CD54/74HCT32	TI TI		
1C6 1C7 1C8 1C9 Miscella	Digital, Microprocessor, 280 Digital, Microprocessor, 280, SIO/O D.C. Regulator, 12V Negative D.C. Regulator, 12V Positive	24807-302 24803-302 24310-901 24309-901	TOS TOS NAT NAT	TMP284C30P TMP284C40P LM79M12C LM78M12C	TI, MOT TI, MOT		
NONE YI	Cable Assy, Flat, 26 Pin, 8 inches Crystal; 6.144MHz	42007-080 28051-002	ORB MID	C1950			
PCB SLAVE DISPLAY ASSEMBLY (SD)							
Capacito C1,2	Alum., Radial, 63V, -20% +100%; 2.2uF	21209-522	SPR	502D 225G063BB1C	PAN		
Integrat IC1 IC2	<u>ed Circuits</u> Digital, Display Driver Digital, Display Driver	24713-302 24712-302	NAT NAT	LM3916 LM3914			
<u>LEDs</u> DS1	LED, Red	25106-003	HP	HLMP-1300	GI		
DS2,3 DS4 DS5	LED, Green LED Array, 9-Yellow, 1-Red LED Array, 6-Green, 3-Yellow, 1-Red	25106-002 25152-000 25151-000	HP ORB ORB	HLMP-1503	GI		
<u>Transist</u> Q1,2	<u>ors</u> Transistor, Signal, NPN	23202-101	MOT	2N4400	FSC		

- (1) See last page for abbreviations
 (2) No Alternate Vendors known at publication
 (3) Actual part is specially selected from part listed, consult Factory
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SPECIFICATIONS AND SOURCES FOR REPLACEMENT PARTS

787A MIC PROCESSOR PCB RS-232 Assy: ICs, Misc.; PCB Slave Display Assy

DES	DESCRIPTION	ORBAN P/N	<u>(1)</u>	VENDOR P/N	VENDORS (1)	NOTES
PCB SLAVE 1	NTERCONNECT ASSY [S1]					
Capacito	r <u>s</u>					
Ci	Monolythic Ceramic, 50V, 20%; 0.1uF	21123-410	SPR	1C25 Z5U104M050B	KEM	
C2	Alum., Axial, 40V, -10% +100%; 1000uF	21224-810	SIE	B41010-1000-40	PAN	
C3	Monolythic Ceramic, 50V, 20%; 0.1uF	21123-410	SPR	1C25 25U104M050B	KEM	
C4 C5	Alum., Radial, 25V, -20% +100%; 100uF Monolythic Ceramic, 50V, 20%; 0.1uF	21206-710 21123-410	PAN	ECE-A1EV1015	VEN	
C9	Alum., Axial, 40V, -10% +100%; 1000uF	21123-410	SPR SIE	1C25 25U104M050B B41010-1000-40	KEM Pan	
C7	Monolythic Ceramic, 50V, 20%; 0.1uF	21123-410	SPR	1C25 Z5U104M050B	KEM	
C8	Alum., Radial, 25V, -20% +100%; 100uF	21206-710	PAN	ECE-A1EV101S	KLII	
C9	Monolythic Ceramic, 50V, 20%; 0.1uF	21123-410	SPR	1C25 Z5U104M050B	KEM	
C10	Alum., Axial, 40V, -10% +100%; 1000uF	21224-810	SIE	B41010-1000-40	PAN	
C11	Monolythic Ceramic, 50V, 20%; 0.1uF	21123-410	SPR	1C25 Z5U104M050B	KEM	
C12	Alum., Radial, 25V, -20% +100%; 100uF	21206-710	PAN	ECE-A1EV101S		
C13	Met. Polyester, 100V, 10%; 0.1uF	21441-410	WIM	MKS-4100V5.0.1	WES, SIE	
C14	Alum., Axial, 100V, -20% +20%; 100uF	21226-710	ME	3074HH101T100JPB	PAN	
C15	Met. Polyester, 100V, 10%; 0.1uF	21441-410	WIM	MKS-4100V5.0.1	WES, SIE	
C16	Alum, Radial, 63V, -20% +100%; 33uF	21209-633	SPR	502D 336G063CC1C	PAN	
C17,18	Met. Polyester, 100V, 10%; 0.01uF	21441-310	WES	160C 103K630	SIE, WIM	
Diodes						
CR1	Diode, Rectifier, 400V, 1A	22201-400	MOT	1N4004	MANY	
CR2	Diode, Zener, 10; 51V	22004-510		1N4757A	MANY	
Integra	ed Circuits					
103	D.C. Regulator, 5V Positive	24307-901	NAT	LM78M05C	TI, MOT	
Miscella	neous					
D.O.	C-bl- A	45008 050				
P2 P4	Cable Assy, Flat, 40 Pin, 2 inches Cable Assy, Flat, 16 Pin, 6.5 inches	42008-020 40056-065	ORB ORB			
	•	10000 000	UKB			
Switches	<u>.</u>					
SW1	Switch, Single, Push-Push; 4PDT	26116-000	SCH	F014UEEB01BAG		
Transis	<u>ors</u>					
Q1	Transistor, Power, NPN; TO-220	23604-201	TI	T1P122	RCA	
Q2	Transistor, Signal, NPN	23202-101		2N4400	FSC	
	-					

VEN

ALTERNATE

FOOTNOTES:

REF

- (1) See last page for abbreviations
 (2) No Alternate Vendors known at publication
 (3) Actual part is specially selected from part listed, consult Factory
- (4) Realignment may be required if replaced, see Circuit Description and/or Alignment Instructions

SPECIFICATIONS AND SOURCES FOR REPLACEMENT PARTS

787A MIC PROCESSOR PCB Slave Interconnect Assy

	Orhan Model 787A

REMOTE CO	ONTROL FINAL ASSEMBLY					
LEDs						
DS1,2	LED, Red	25103-000	CI	MV-5053		
Miscel	laneous					
NONE NONE	Cable Assy, Flat, 14 Pin, 2.5 inches Cable Assy, Flat, 16 Pin, 2.5 inches	42006-025 42009-025	ORB ORB			
SLAVE UNI	T FINAL ASSEMBLY					
Miscel	<u>laneous</u>					
NONE NONE NONE NONE NONE NONE	Cable Assy, Flat, 37 Pin, "D" Conn. Cable Assy, Flat, 37 Pin, 8 inches Cable Assy, Flat, 37 Pin, 3.5 inches Sub Assy, 10 Position Barrier Strip Sub Assy, XLR Connector, Output Sub Assy, Heatsink Regulator Sub Assy, XLR Connector, Input	42011-000 42010-080 42010-035 40064-000 40066-000 40068-002 40065-000	ORB ORB ORB ORB ORB ORB			Main unit to slave unit Internal main unit
SUB ASSY,	10 POSITION BARRIER STRIP					
<u>Capaci</u>	itors					
C1-7 None	Ceramic Disc, 1KV, 10%; 0.001uF Ceramic Disc, 1KV, 10%; 0.001uF	21112-210 21112-210		DD-102 DD-102	MUR MUR	TB1 TB2
SUB ASSY,	HEATSINK REGULATOR					
Integr	rated Circuits					
1C1 1C2 1C3	D.C. Regulator, 15V Positive B.C. Regulator, 15V Negative D.C. Regulator, 5V Positive	24304-901 24303-901 24307-901	NAT NAT NAT	LM78M15UC LM79M15AUC LM78M05C	TI, MOT TI, MOT TI, MOT	Main unit only

VEN

(1)

VENDOR P/N

ORBAN P/N

ALTERNATE

VENDORS (1)

NOTES

FOOTNOTES:

REF

DES

DESCRIPTION

- (1) See last page for abbreviations(2) No Alternate Vendors known at publication
- (3) Actual part is specially selected from part listed, consult Factory
- (4) Realignment may be required if replaced, see Circuit Description and/or Alignment Instructions

SPECIFICATIONS AND SOURCES FOR REPLACEMENT PARTS

787A MIC PROCESSOR

Remote Ctrl Final Assy; Slave Final Assy; Sub Assy, 10 Position Barrier Strip; Sub Assy, Heatsink Regulator

AB	Allen-Bradley Co., Inc. 1201-T South Second Street Milwaukee, WI 53204
AD	Analog Devices, Inc. One Technology Way PO Box 9106 Norwood, MA 02062-9106
AKG	AKG Acoustics, Inc. 1525 Alvarado Street San Leandro, CA 94577
AM	Amphenol Corporation 358 Hall Avenue Wallingford, CT 06492
BEK	Beckman Industrial Corporation 4141 Palm Street Fullerton, CA 92635-1025
BEL	Belden Electronic Wire & Cable PO Box 1980 Richmond, IN 47374
BRN	Bourns, Inc Resistive Components Group 1200 Columbia Avenue Riverside, CA 92507
BUS	Bussmann Division Cooper Industries PO Box 14460 St. Louis, MO 63178
CD	Cornell-Dubilier Elec. 1700 Rte. 23 North Wayne, NJ 07470
CLIF	Cliff Electronics Company, Inc. 4876 East Second Street Benicia, CA 94510
CRL	Mepcopal/Centralab See Mepcopal
CSC	Crystal Semiconductor Corporation 4210-T. South Industrial Dr. Austin, TX 78744
CTS	CTS Corporation 907 North West Blvd. Elkhart, IN 46514
CW	CW Industries 130 James Way Southampton, PA 18966
DBX	dbx A division of AKG Acoustics, Inc. 1525 Alvarado Street San Leandro, CA 94577

DEL	Delta Products Corp 361 Fairview Way Milpitas, CA 95035	KEY	Keys 31-07 Astor
DUR	Duracell, Inc. Berkshire Industrial Park Bethel, CT 06801	LFE	Little A Su 800 I Des I
ELSW	Electro Switch 77 King Avenue Weymouth, MA 02188	LT	Linea 1630 Milpi
EMI	Emico Inc. 123 Main Street Dublin, PA 18917	LUMX	_
EXR	Exar Corporation 2222 Qume Dr. PO Box 49007 San Jose, CA 95161-9007	MAL	Mallo Emha 4760 India
FR	Fair-Rite Products Corp. PO Box J Wallkill, NY 12589	MAR	Marq 2711 Caze
FSC	Fairchild Camera & Instr. Corp. See National Semiconductor	MAT	Mats One
GI	General Instruments Optoelectronics Division See Quality Technologies	ME	Secar Mepo
НА	Harris Semiconductor 2460 N 1st Street Suite 200		A No 1146 San I
но	San Jose, CA 95131-0124 Hoyt Elect. Inst. Works 19 Linden St.	MID	Holli Holli 357 I
НР	Penacook, NH 03303 Hewlett-Packard Co. Components Group 640 Page Mill Road	MIL	J.W. Bell 306 I Gard
INS	Palo Alto, CA 94304 Intersil, Inc. See Harris Semiconductor	мот	Moto PO B Phoe
ITW	ITW Switches An Illinois Tool Works Co. 6615 W. Irving Park Rd. Dept. T	MUR	Mura 2200 Smyr
КВ	Chicago, IL 60634 Kingbright USA Corporation 225 Brea Canyon Road	NAT	Natio 2900 PO E
KEM	City of Industry, CA 91789 KEMET Electronics Corporation Post Office Box 5928 Greenville, South Carolina 29606	NEC	NEC 159 Bax
	=		

KEY	Keystone Electronics Corp. 31-07 20th Rd. Astoria, NY 11105
LFE	Littlefuse A Subsidiary of Tracor, Inc. 800 E. Northwest Hwy Des Plaines, IL 60016
Л	Linear Technology Corp. 1630 McCarthy Blvd. Milpitas, CA 95035
LUMX	Lumex Opto/Components Inc. 292 E. Hellen Road Palatine, IL 60067
MAL	Mallory Capacitor Co. Emhart Electrical/Electronic Gr. 4760 Kentucky Ave Indianapolis, IN 46241
MAR	Marquardt Switches, Inc. 2711-TR Route 20 East Cazenovia, NY 13035
MAT	Matsushita Electric Corp of America One Panasonic Way Secaucus, NJ 07094
ME	Mepcopal/Centralab A North American Phillips Corp. 11468 Sorrento Valley Road San Diego, CA 92121
MID	Hollingsworth/Wearnes Hollingsworth Solderless Terminal Div. 357 Beloit Street Burlington, WI 53105
MIL	J.W. Miller Division Bell Industries 306 E. Alondra Gardena, CA 90247
TOM	Motorola Semiconductor PO Box 20912 Phoenix, AZ 85036
MUR	Murata Erie North America 2200 Lake Park Drive Smyrna, GA 30080
NAT	National Semiconductor Corp. 2900 Semiconductor Drive PO Box 58090 Santa Clara, CA 95051
NEC	NEC Technologies 159 Swanson Bax Braugh, MA 01719

NEL	NEL Frequency Controls, Inc. 357 Beloit Street Burlington, WI 53105
NOB	Noble U.S.A., Incorporated 5450 Meadowbrook Industrial Ct. Rolling Meadows, IL 60008
окі	OKI Semiconductor 785 N. Mary Ave. Surmyvale, CA 94086-2909
ОНМ	Ohmite Manufacturing Company 3601 Howard Street Skokie, IL 60076
ORB	Orban A division of AKG Acoustics, Inc. 1525 Alvarado Street San Leandro, CA 94577
PAN	Panasonic Industrial Company Two Panasonic Way 7E-2T Secaucus, NJ 07094
QT	Quality Technologies, Inc. 610 North Mary Ave. Sunnyvale, CA 94086
RAL	Raltron Electronics Corp. 9550 Warner Ave. Fountain Valley, CA 92708
RAY	Raytheon Company Semiconductor Division 350 Ellis Street Mountain View, CA 94039
RCA	RCA Solid State See Harris Semiconductor
ROHM	Rohm Corporation 8 Whatney Irvine, CA 92718
SAE	Stanford Applied Engineering, Inc 340 Martin Avenue Santa Clara, CA 95050
SAN	Sangamo Weston Inc. Capacitor Division See Comell-Dubilier
SCH	ITT Schadow, Inc. 8081 Wallace Road Eden Prairie, MN 55344
SIE	Siemens Components Inc. Heimann Systems Div. 186 Wood Avenue South Iselin, NJ 08830

SIG	Philips Components - Signetics North American Phillips Corp. 811 E. Arques Sunnyvale, CA 94088
SPR	Sprague Electric Co. 41 Hampden Road PO Box 9102 Mansfield, MA 02048-9102
SW	Switchcraft A Raytheon Company 5555 N. Elston Avenue Chicago, IL 60630
TAI	Taiyo America, Inc. 700 Frontier Way Bensenville, IL 60106
TDK	TDK Electronics Corporation 12 Harbor Park Port Washington, NY 11050
TI	Texas Instruments, Inc. PO Box 225012 Dallas, TX 75265
TOS	Toshiba America, Inc. 9740 Irvine Blvd. Irvine, CA 92718
TRW	TRW Electronics Components Connector Division 1501 Morse Avenue Elk Grove Village, IL 60007
VARO	Varo Semiconductor, Inc. PO Box 469013 Garland, TX 75046-9013
WES	Westlake See Mallory Capacitor Co.
WIM	The Inter-Technical Group Inc. Wima Division PO Box 23 Irvington, NY 10533
ZI	ZILOG Inc. 210 Hacienda Ave. Campbell, CA 95008

Vendor Codes

Schematics, Assembly Drawings

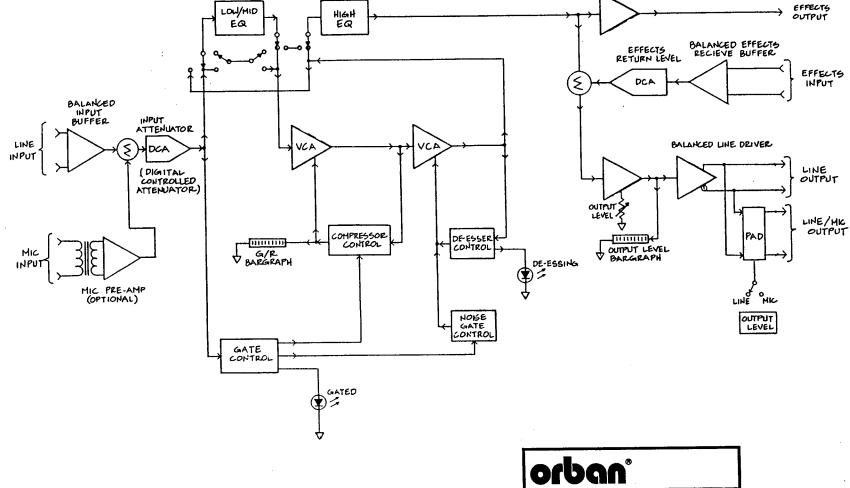
The following drawings are included in this manual:

Page	Board ID	Function	Drawing
6-41		Block Diagram	
6-42	AG	Analog	PC Assembly
6-43	AG	Analog	Schematic
6-44			Schematic
6-46	EQ	Equalizer	PC Assembly
6-47	EQ	Equalizer	Schematic
6-48	DG	Digital & Power Supply	PC Assembly
6-49	DG	Digital & Power Supply	Schematic
6-50			Schematic
6-52	DP	Display	PC Assembly
6-53	DP	Display	Schematic
6-54	SI	Slave Interconnect	PC Assembly
6-55	SI	Slave Interconnect	Schematic
6-56	SD	Slave Display	PC Assembly
6-57	SD	Slave Display	Schematic
6-58	MC	Mic Option	PC Assembly
6-59	MC	Mic Option	Schematic
6-60	DB	Remote Control Display	PC Assembly
6-61	MB	Remote Control	PC Assembly
6-62	MB	Remote Control	Schematic
6-63	SB	Remote Control Switch	PC Assembly
6-64	RI	Remote Interface	PC Assembly
6-65	RI	Remote Interface	Schematic
6-66	MD	Midi Option	PC Assembly
6-67	MD	Midi Option	Schematic
6-68	RS	RS-232	PC Assembly
6-69	RS	RS-232	Schematic

These drawings reflect the actual construction of your unit as accurately as possible. Any differences between the drawings and your unit are almost undoubtedly due to product improvements or production changes since the publication of this manual. Major changes are described in addenda to this manual.

If you intend to replace parts, please read page 6-23.

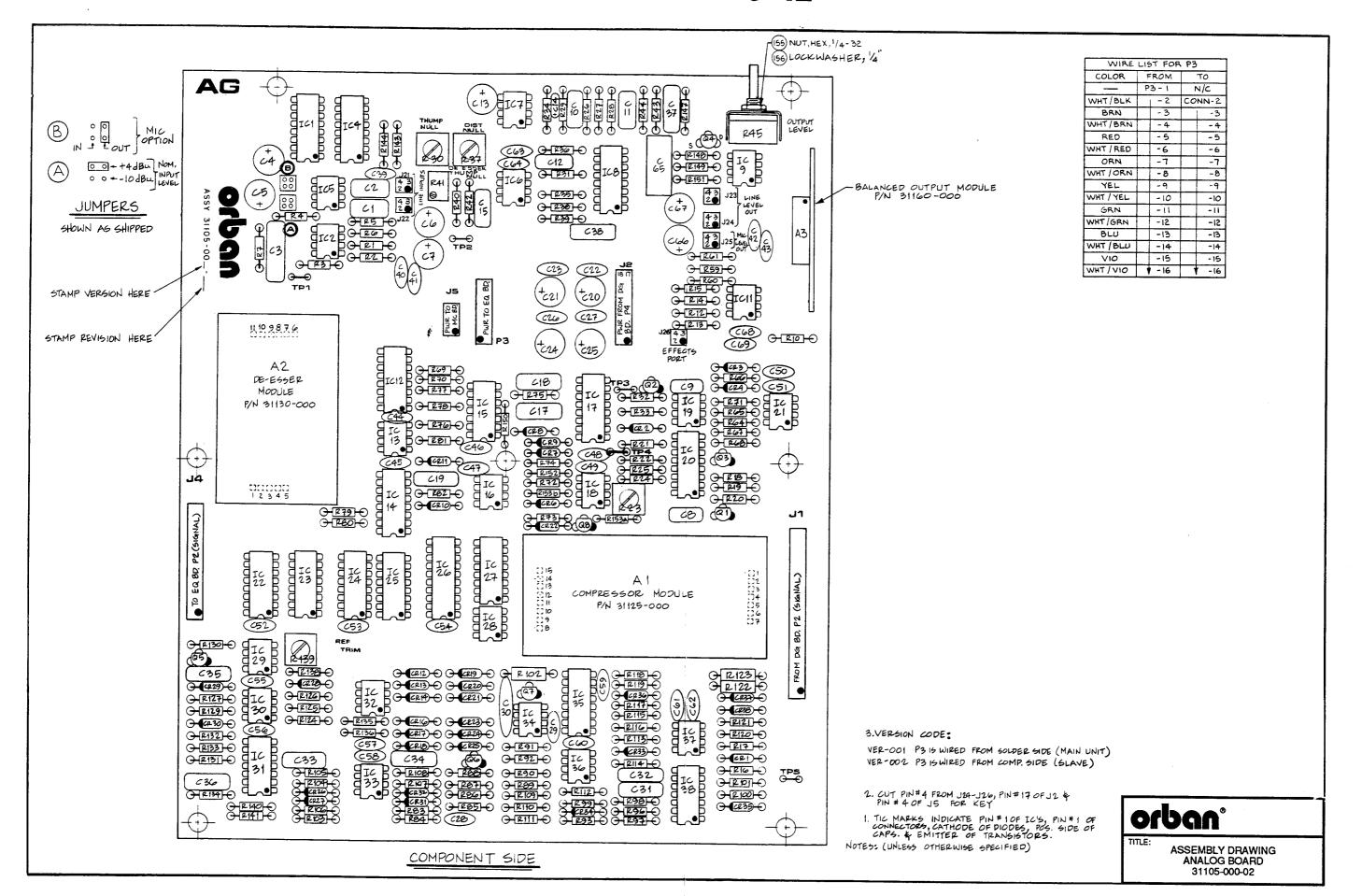
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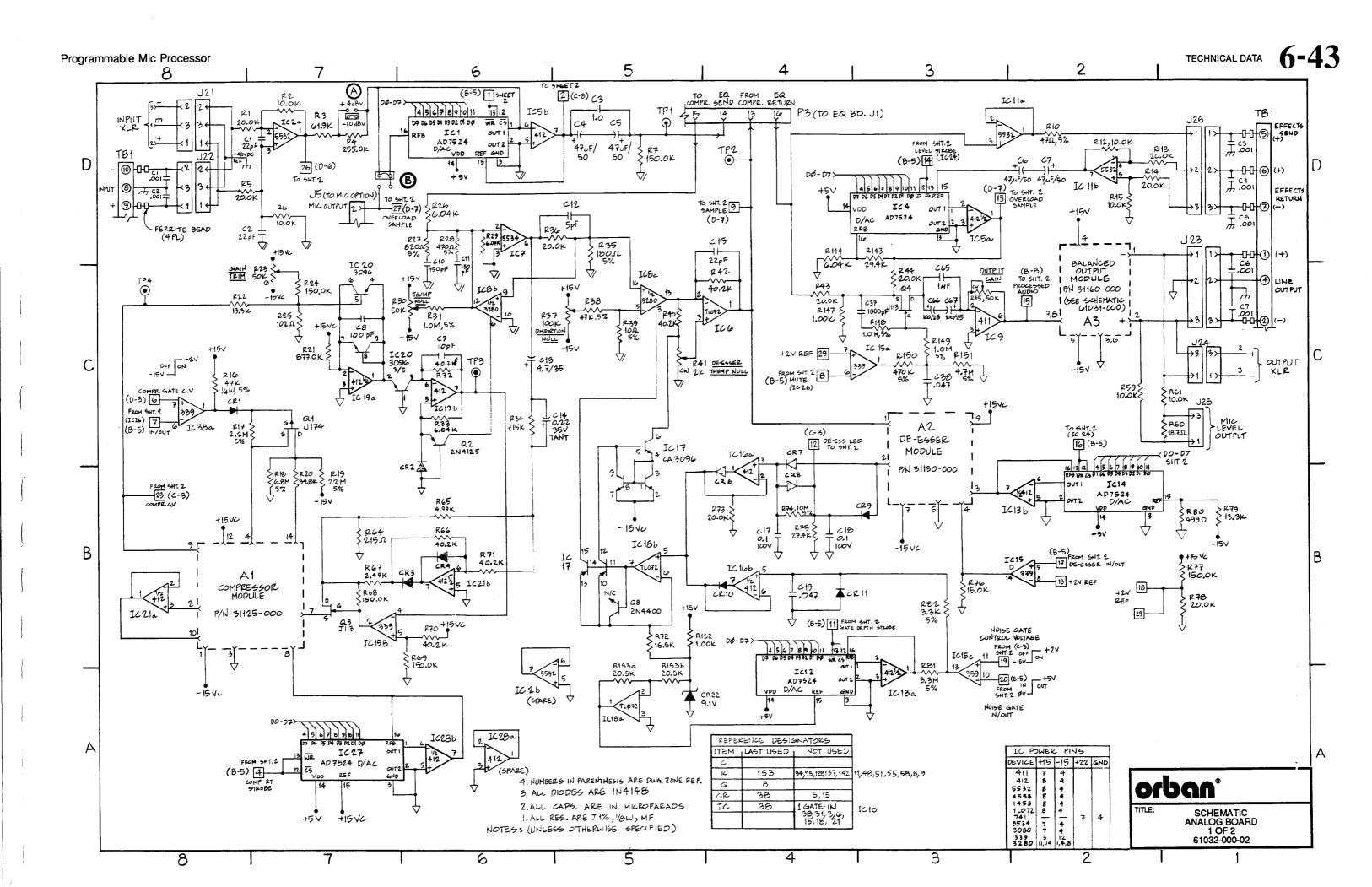


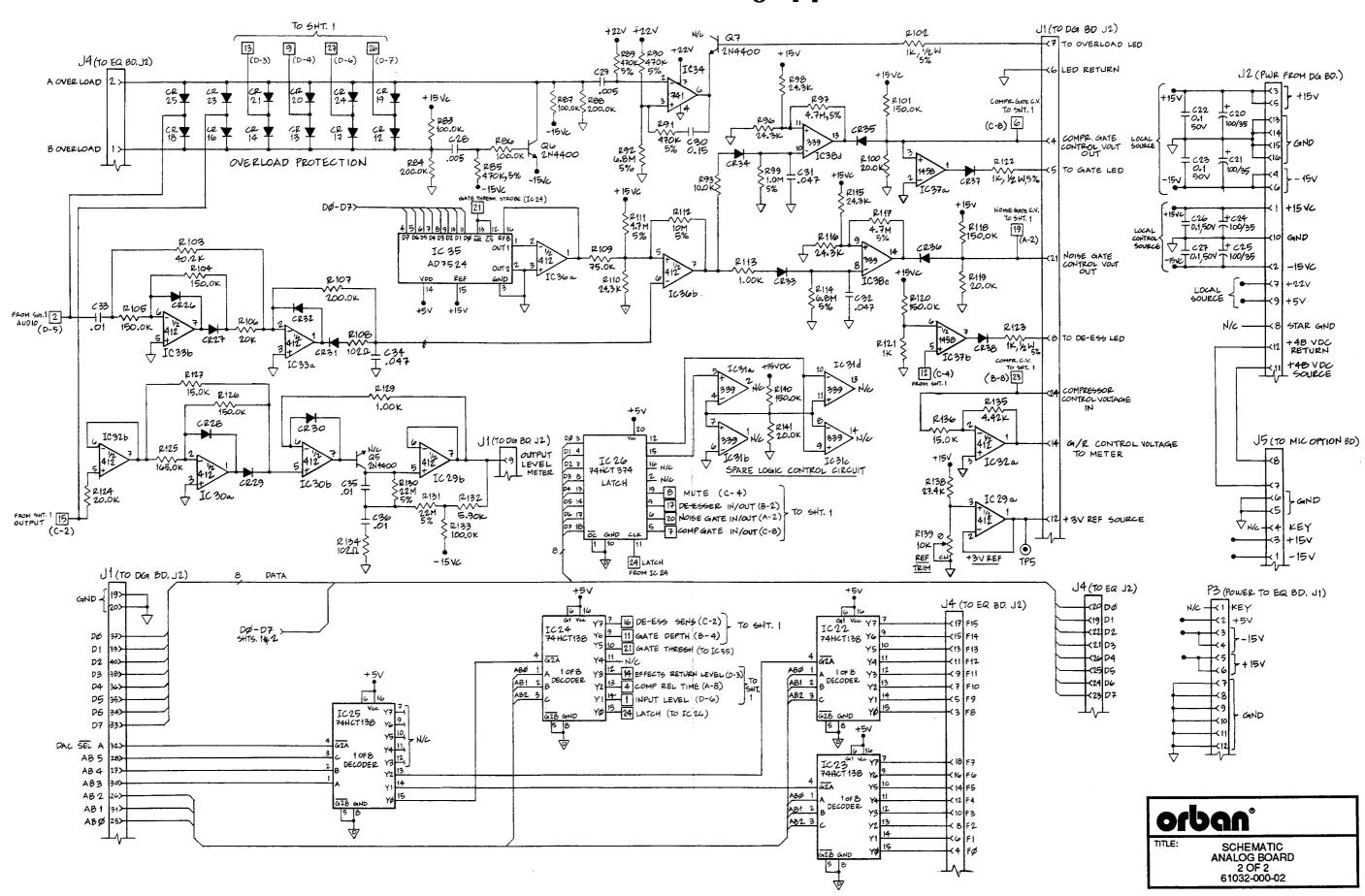
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BLOCK DIAGRAM 787A & 787ASL 60181-000-01

TECHNICAL DATA 6-4







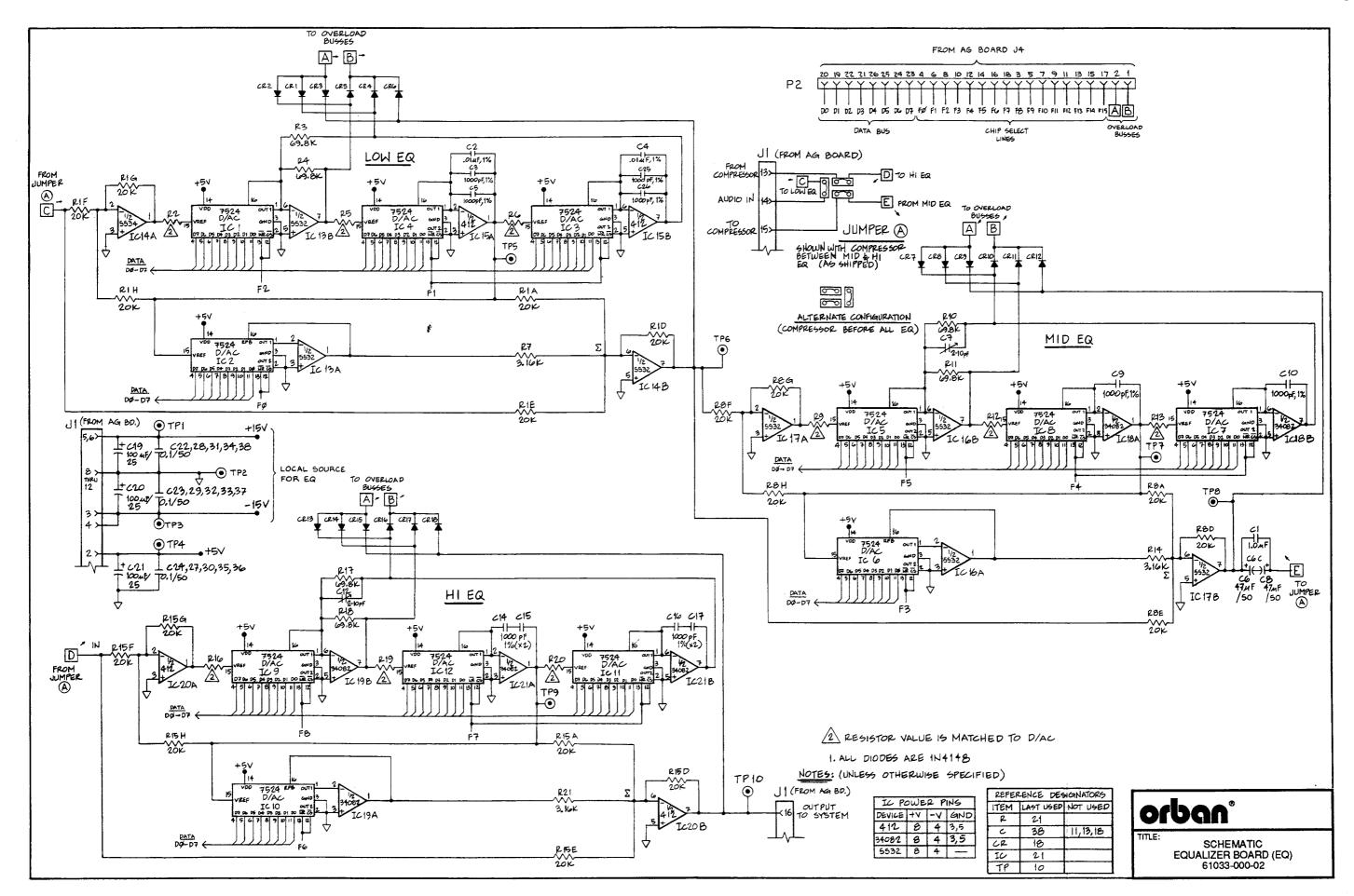
1. TIC MARKS INDICATE PIN 1 OF IC'S, CATHODE OF DIODES, PWS OF CAPS & PIN 1 OF CONNECTORS.

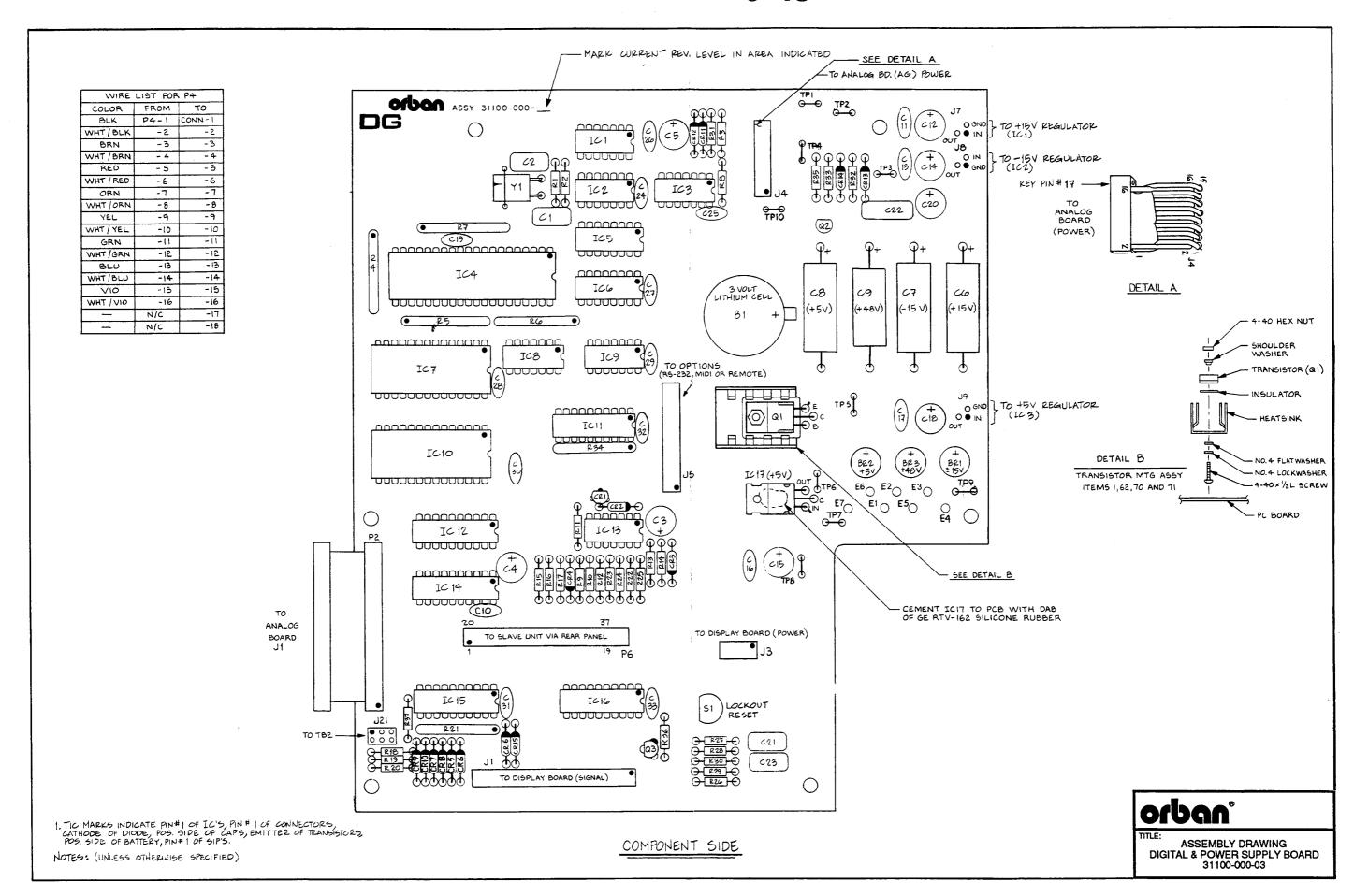
NOTES: (UNLESS OTHERWISE SPECIFIED)

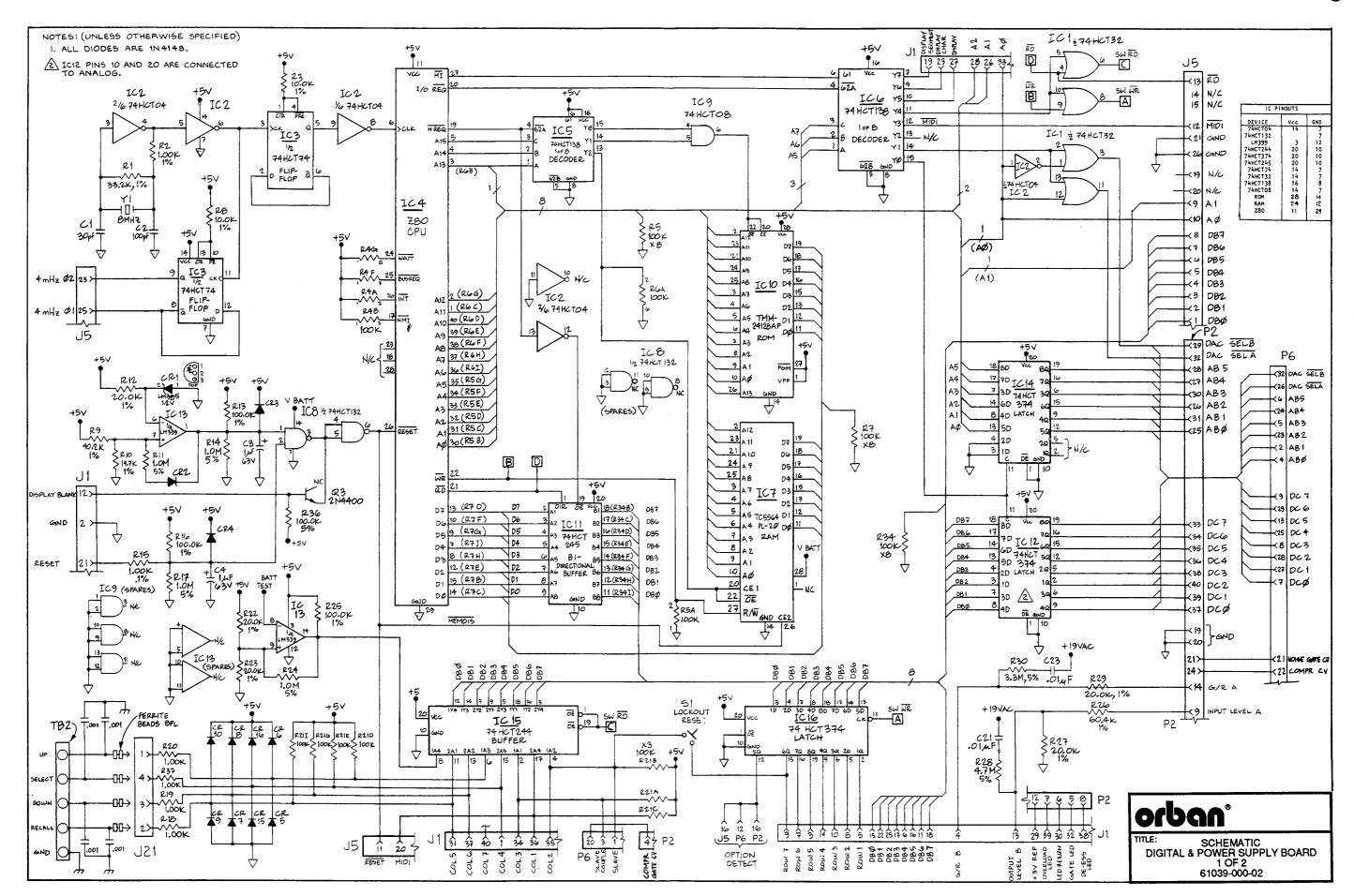
orpau_o

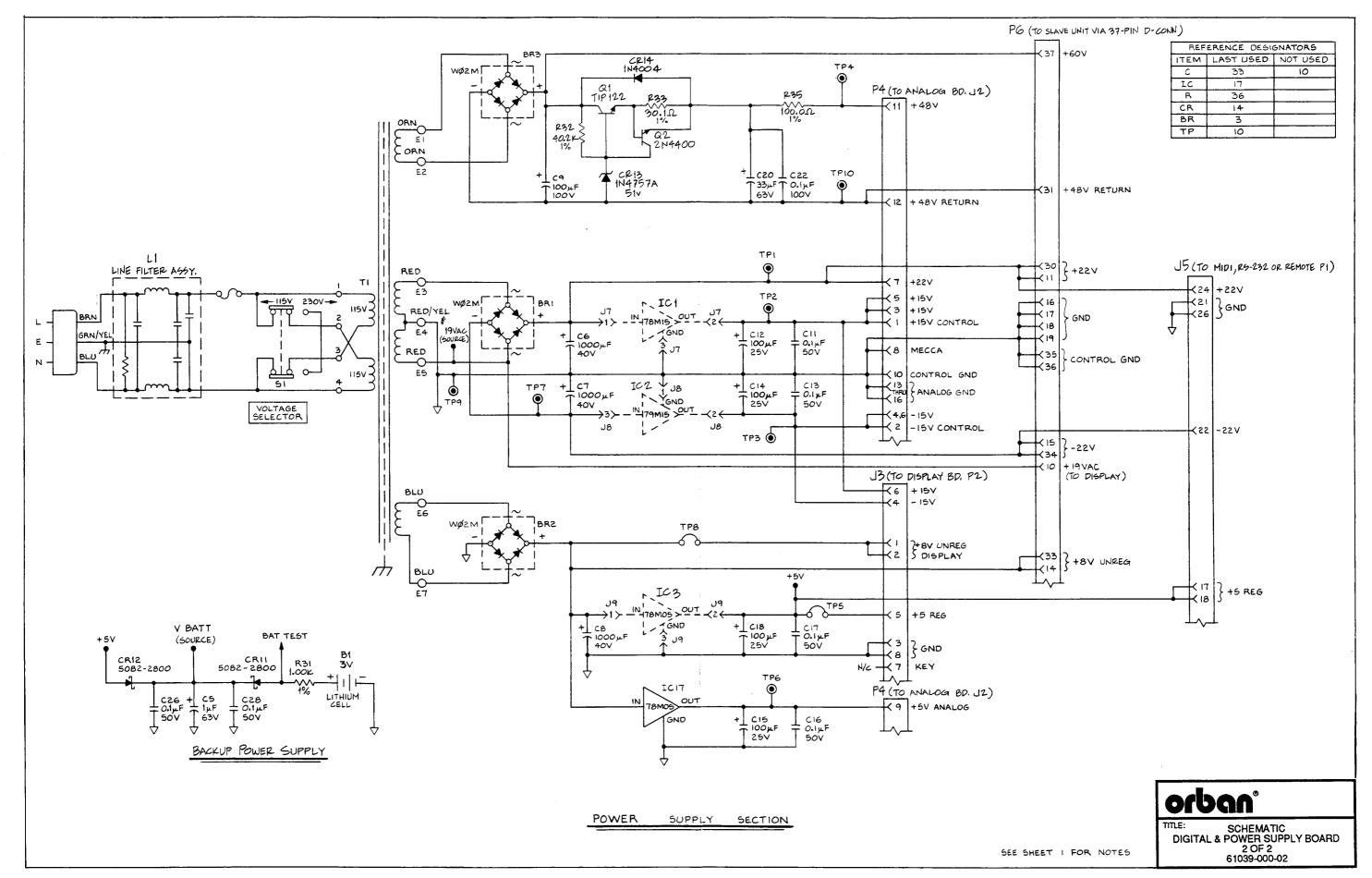
TITLE

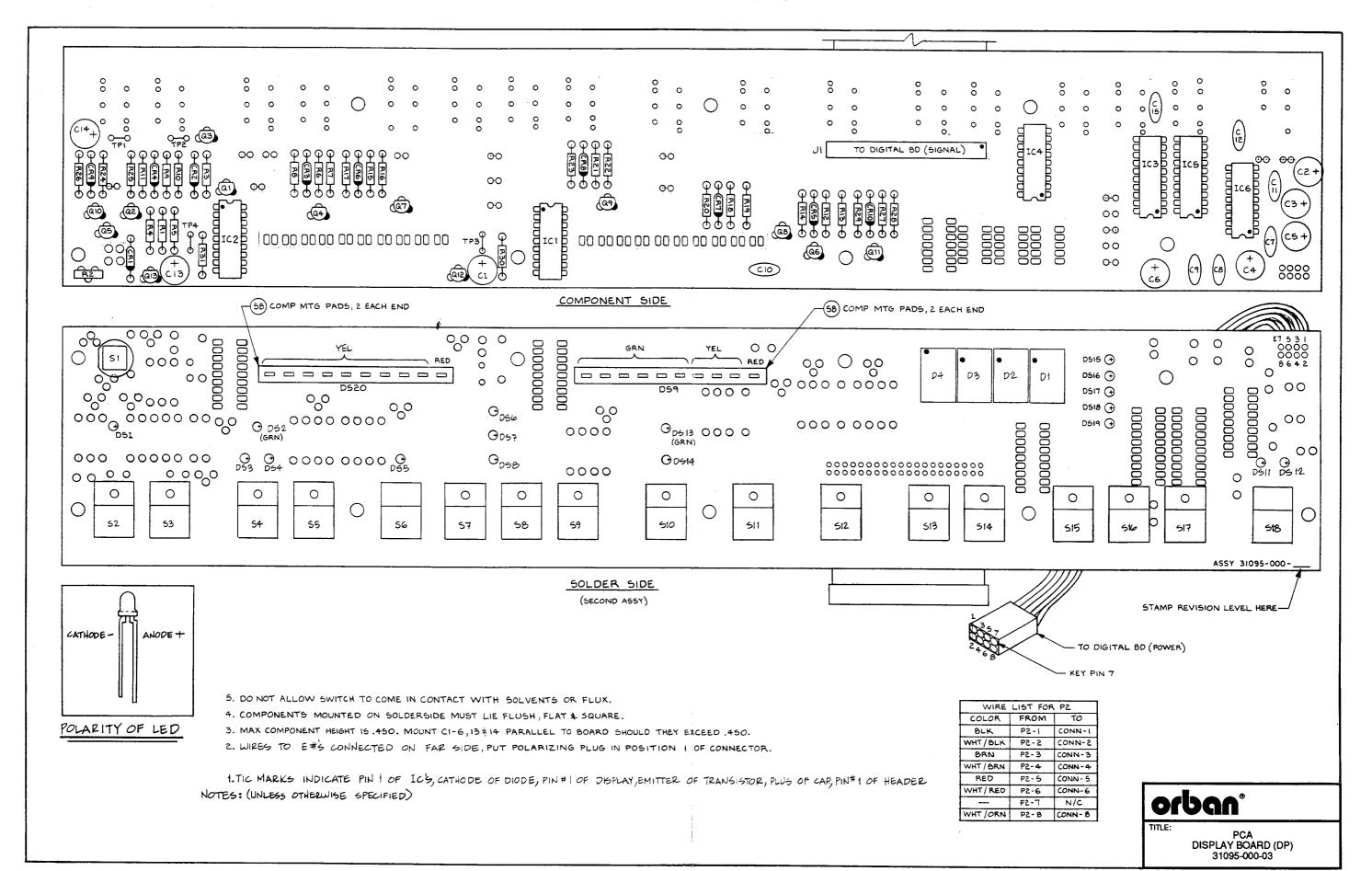
ASSEMBLY DRAWING EQUALIZER BOARD 31110-000-03

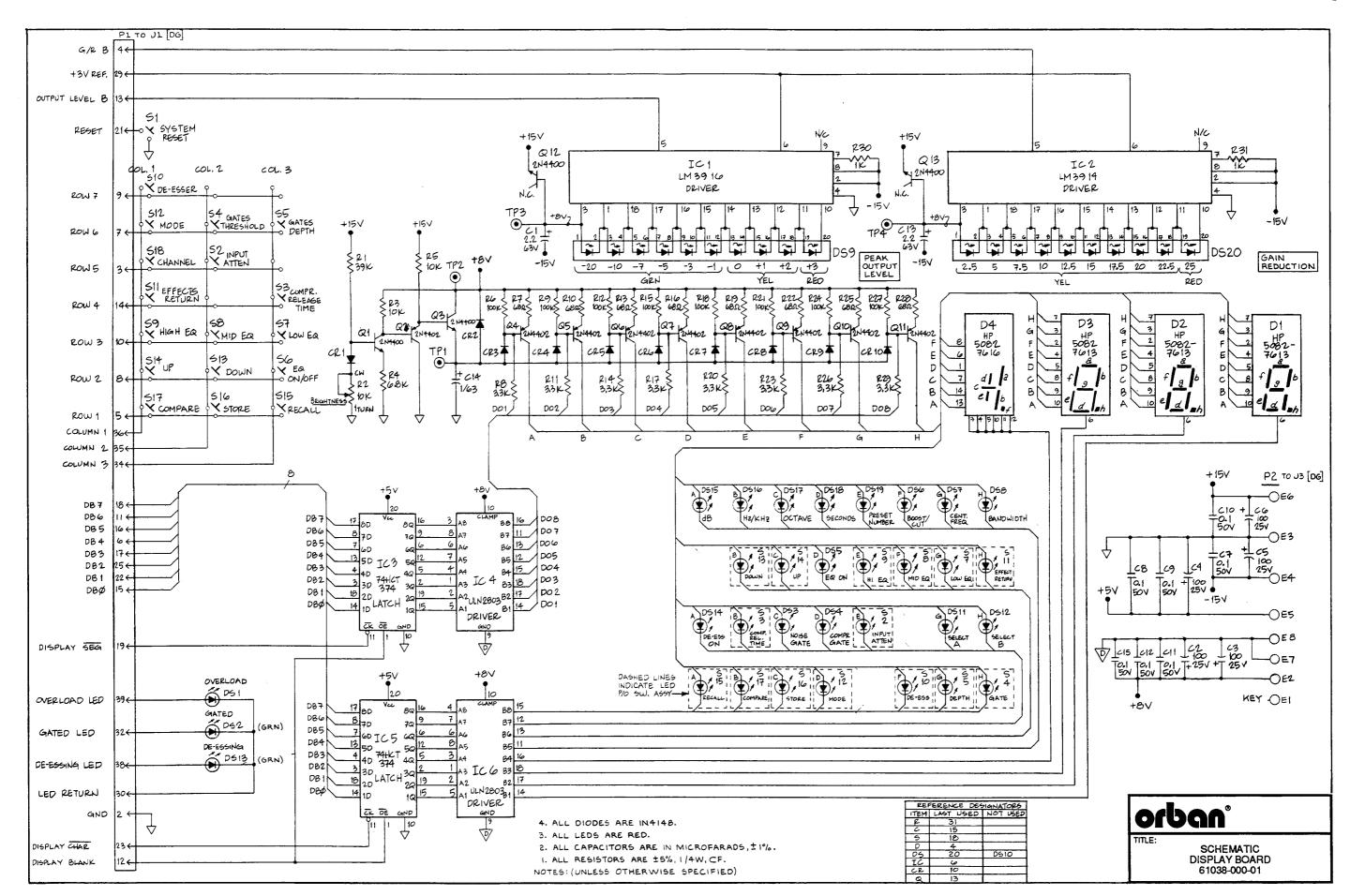


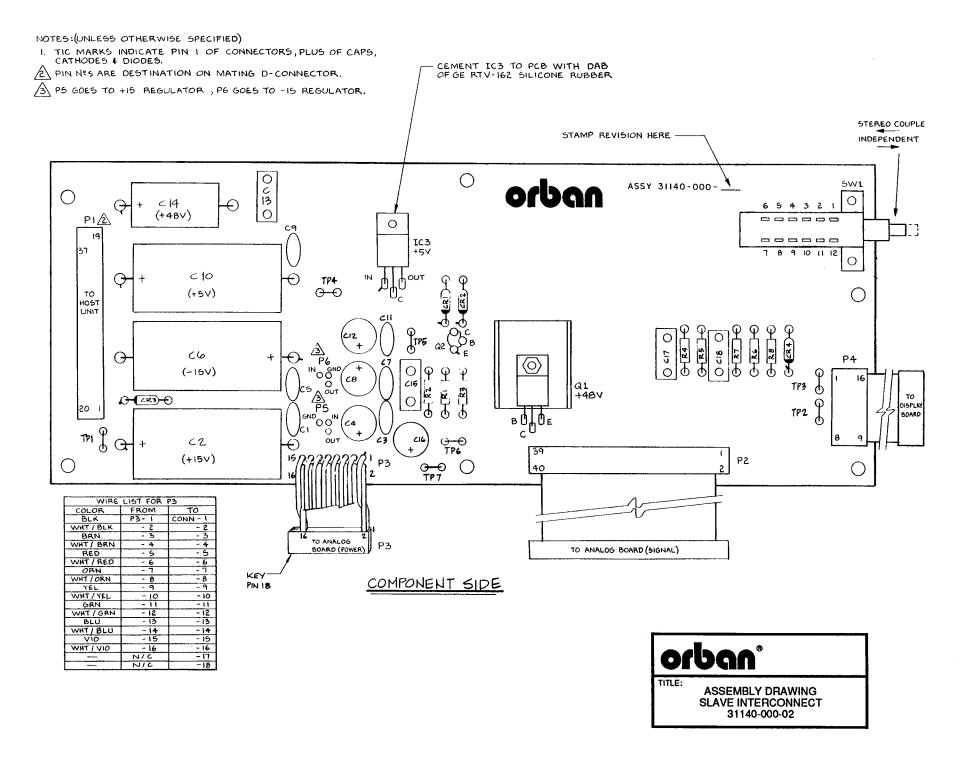


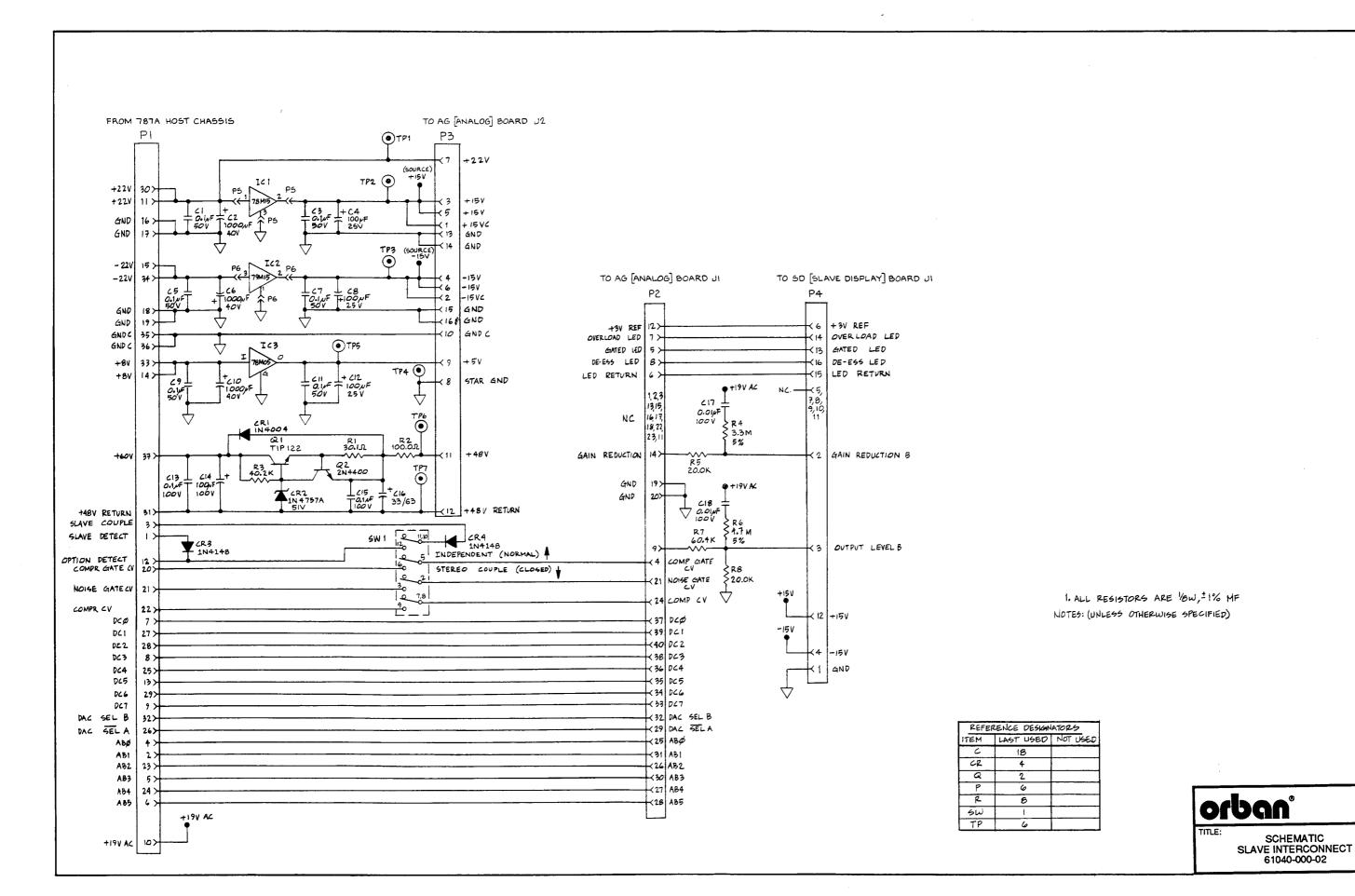


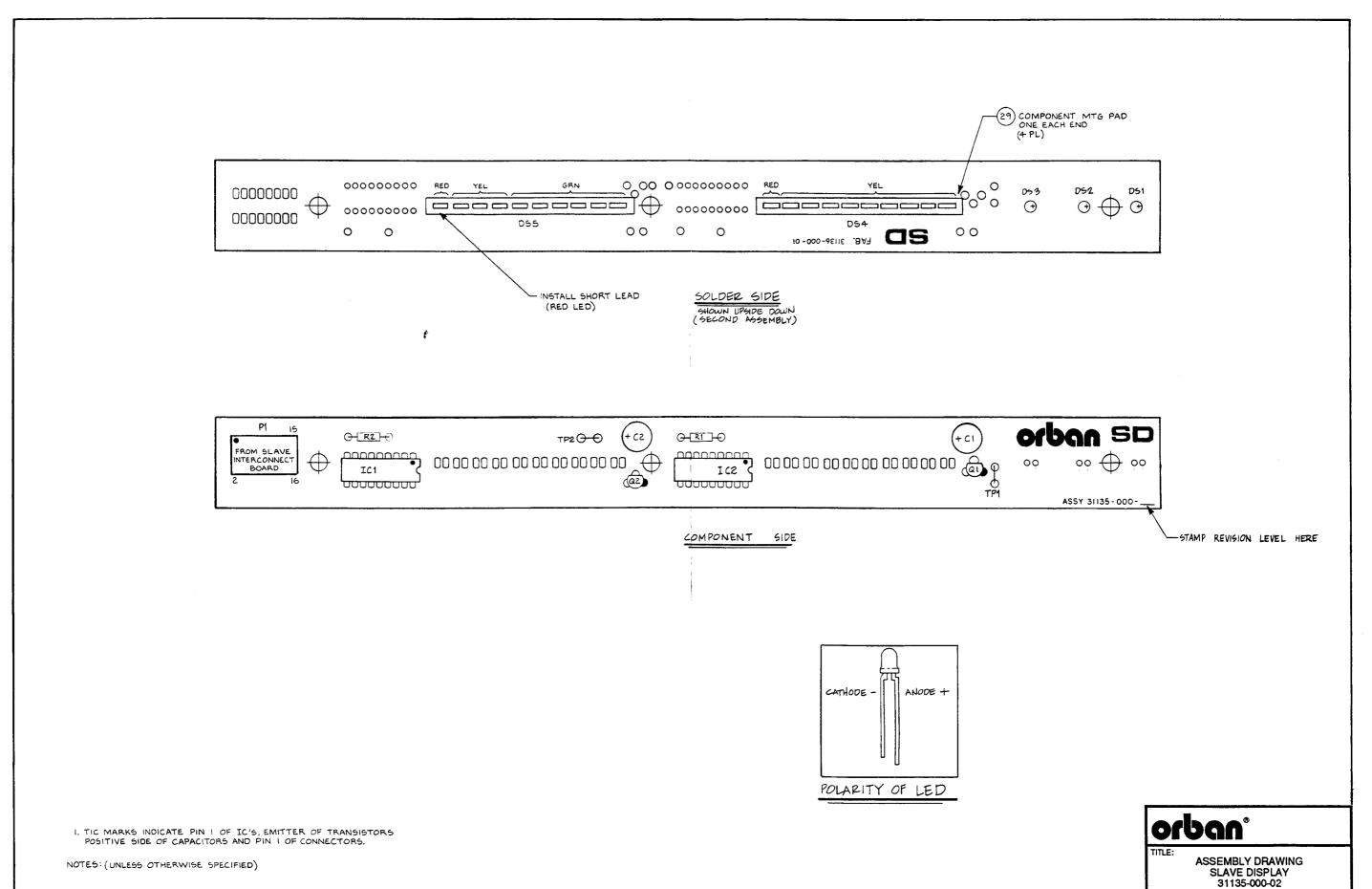


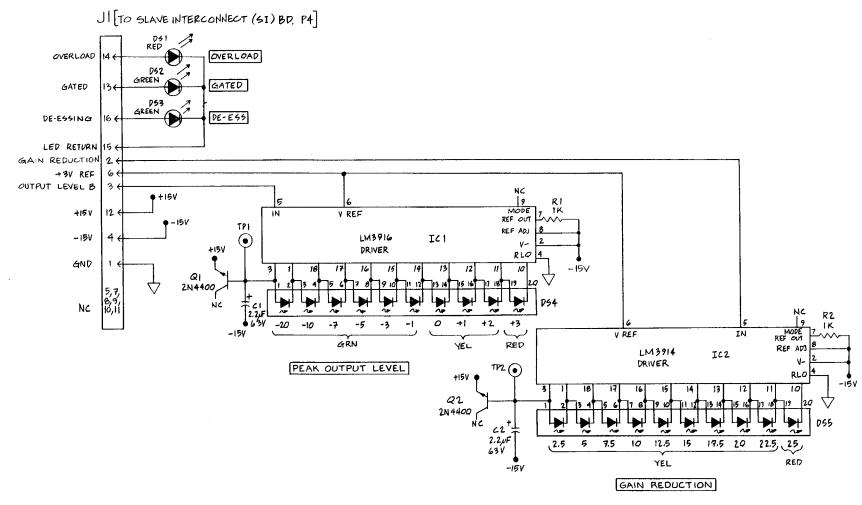








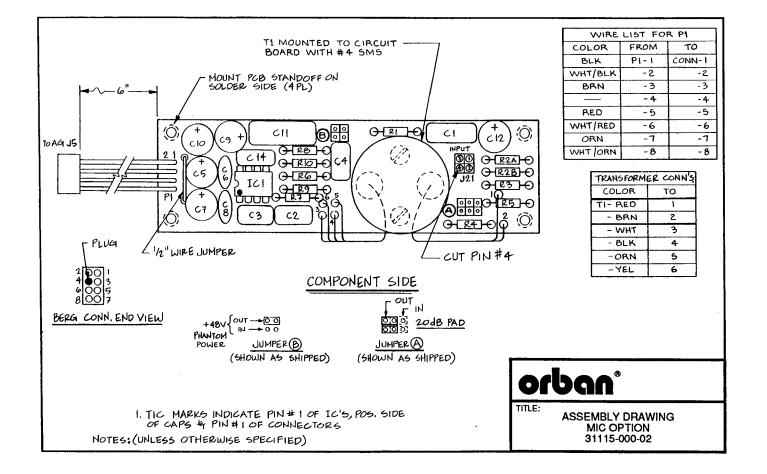


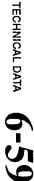


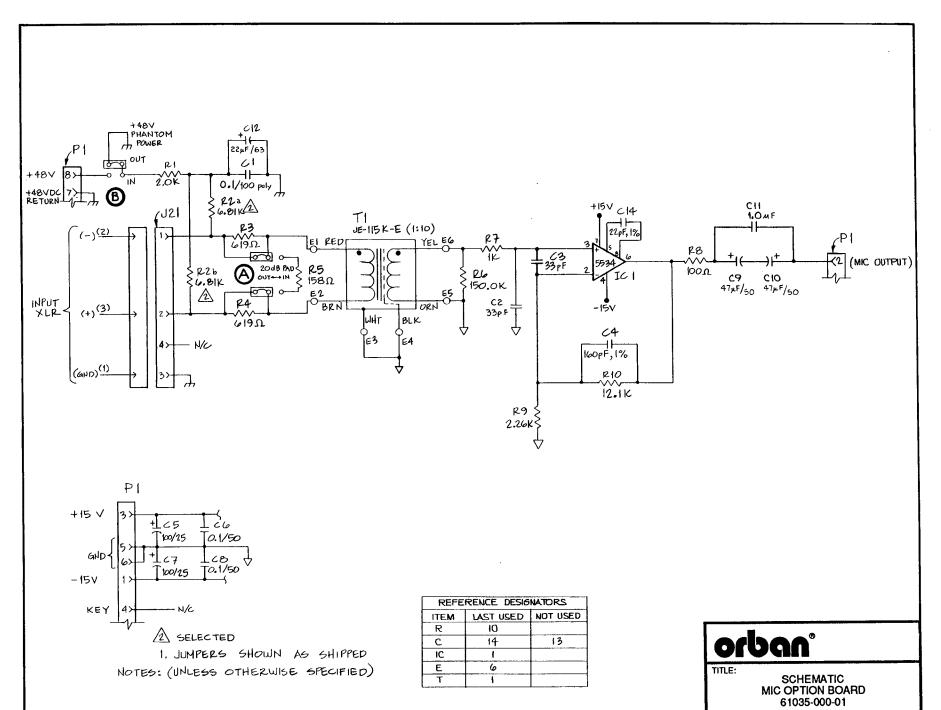
1. ALL RESISTORS ARE 18W, ±1%, MF. NOTES: (UNLESS OTHERWISE SPECIFIED)

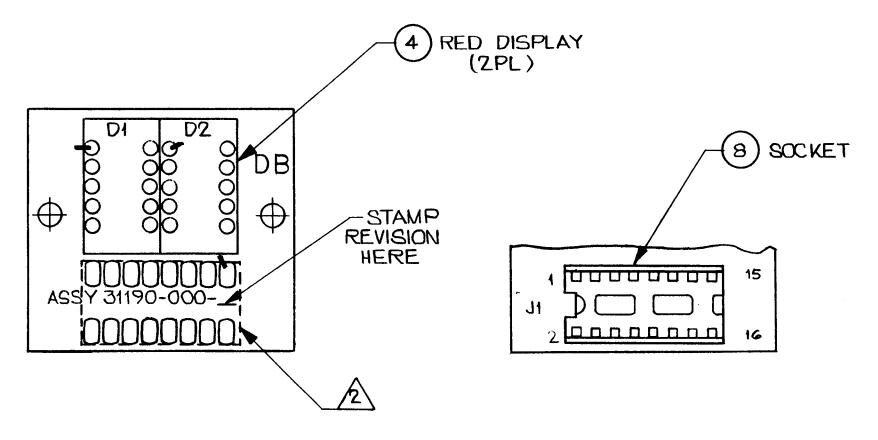
1	REFERENCE DESIGNATORS				
	ITEM	LAST USED	NOT USED		
	C	2			
	05	5			
1	IC	2			
1	a	2			
	R	2			
	TP	2			
	P	1			











COMPONENT SIDE

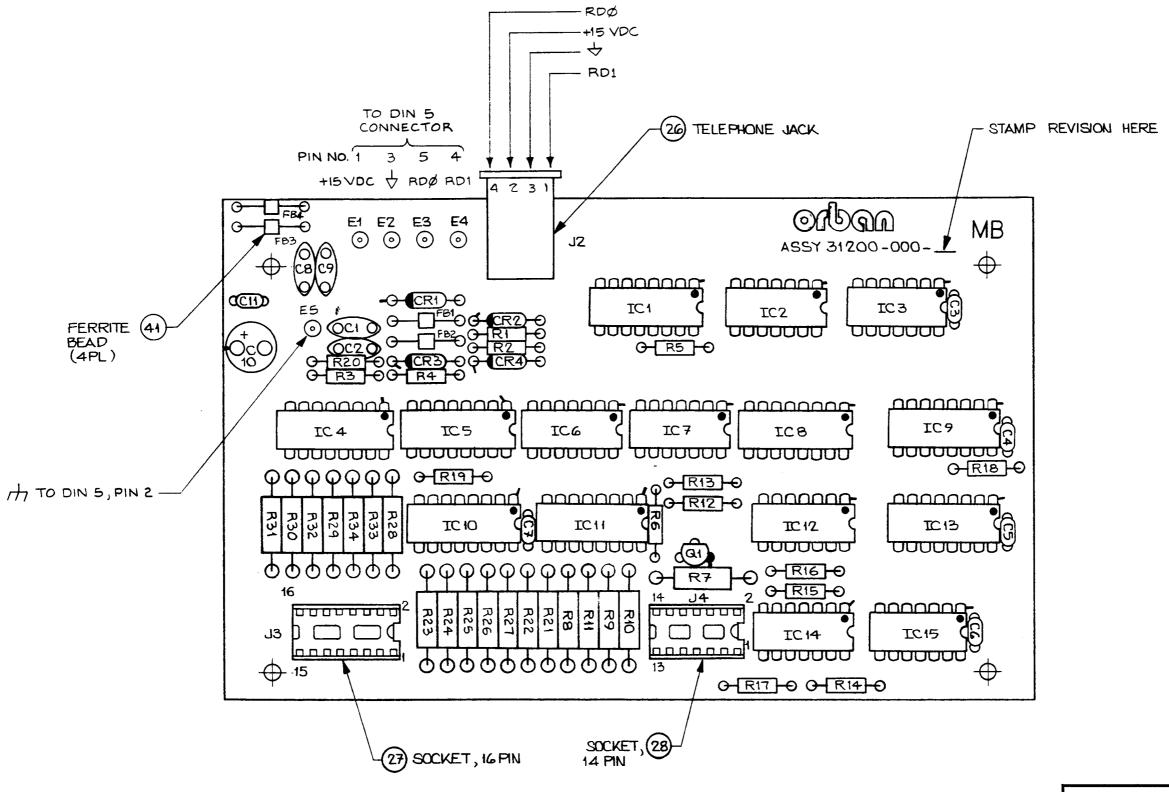
SOLDER SIDE

2. DOTTED COMPONENT TO BE INSTALLED ON SOLDER SIDE AS SHOWN

1. TIC MARKS INDICATE PIN #1 OF LED'S, PIN #1 OF CONNECTOR. NOTES: (UNLESS OTHERWISE SPECIFIED)



PCB ASSEMBLY
REMOTE CONTROL
DISPLAY BOARD (DB)
31190-000-01

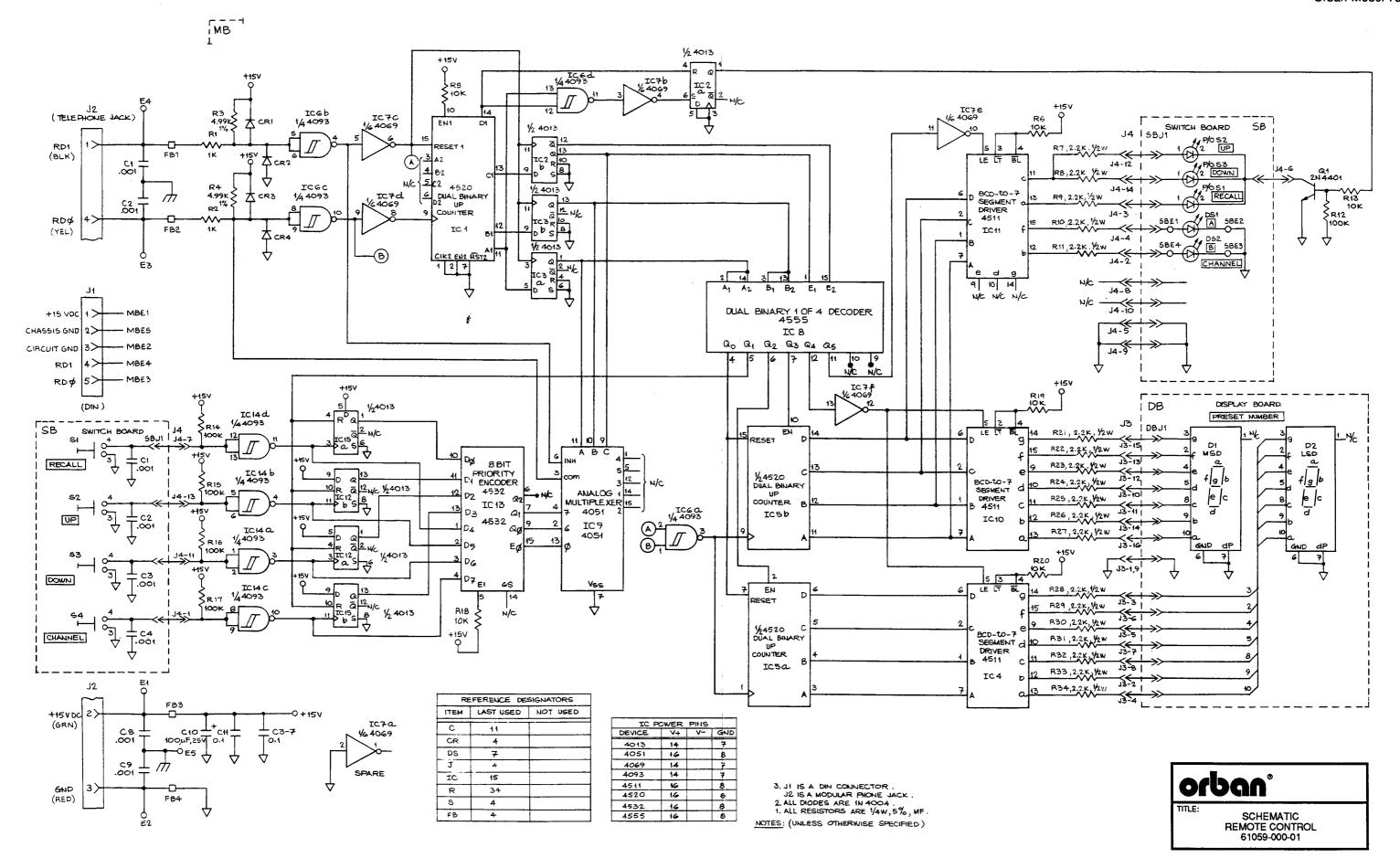


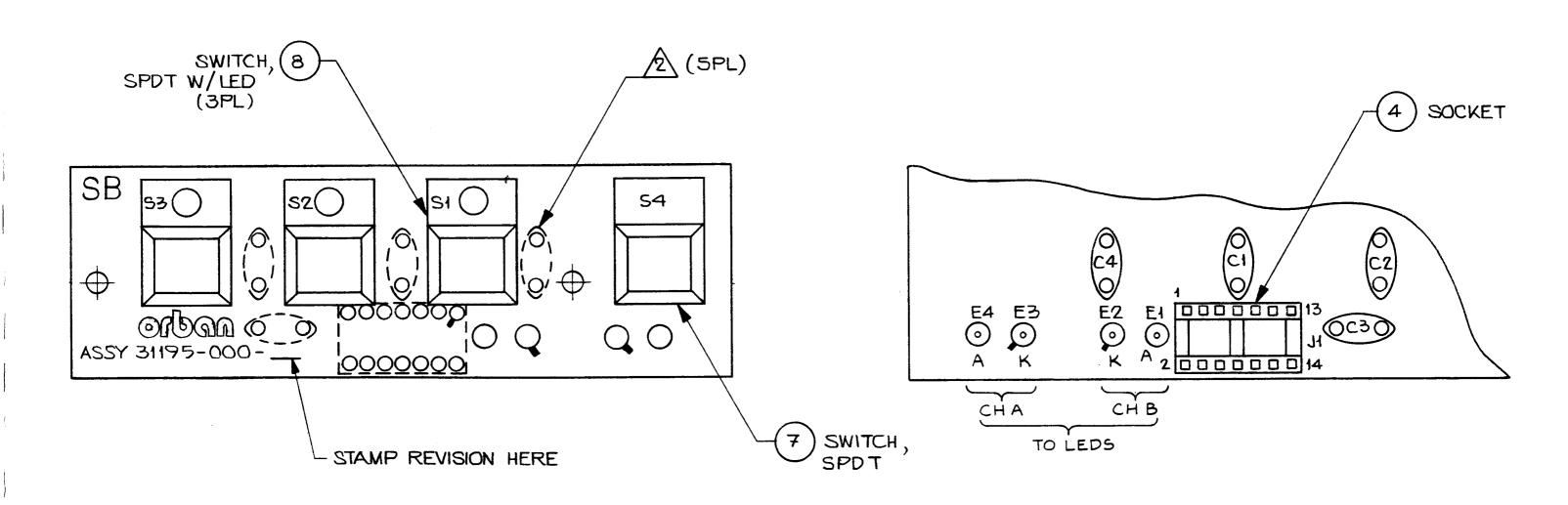
TIC MARKS INDICATE PIN #1 OF IC, PIN #1 OF CONNECTORS, CATHODE OF DIODES, POS. SIDE OF CAPACITORS, EMITTER OF TRANSISTOR.
 REFERENCE SCHEMATIC DWG. NO. 61059-000
 NOTES: (UNLESS OTHERWISE SPECIFIED)

COMPONENT SIDE

orpan,

PCB ASSEMBLY
REMOTE CONTROL (MB)
31200-000-02





COMPONENT SIDE

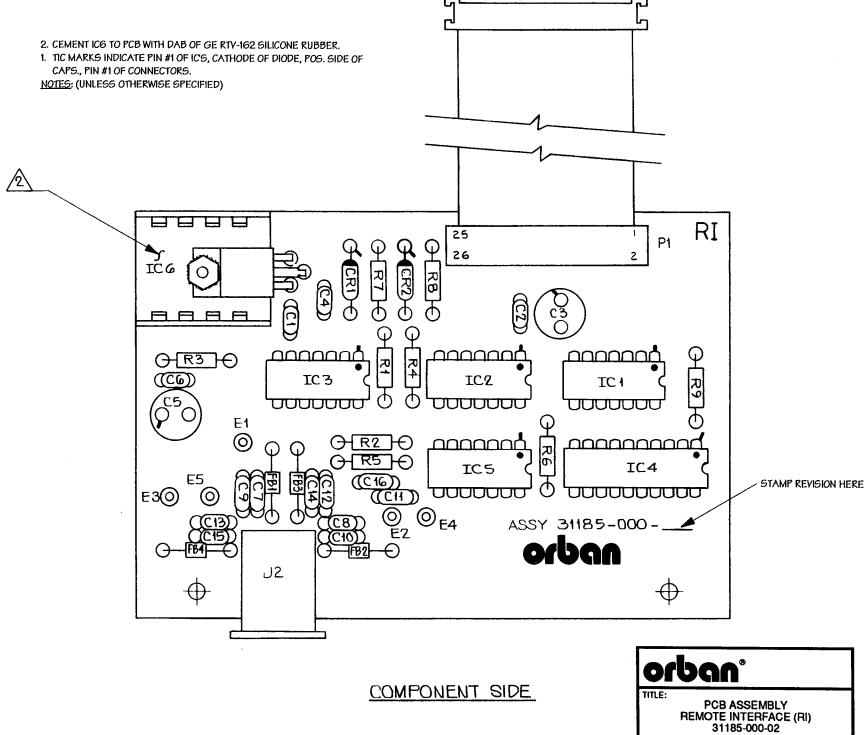
SOLDER SIDE

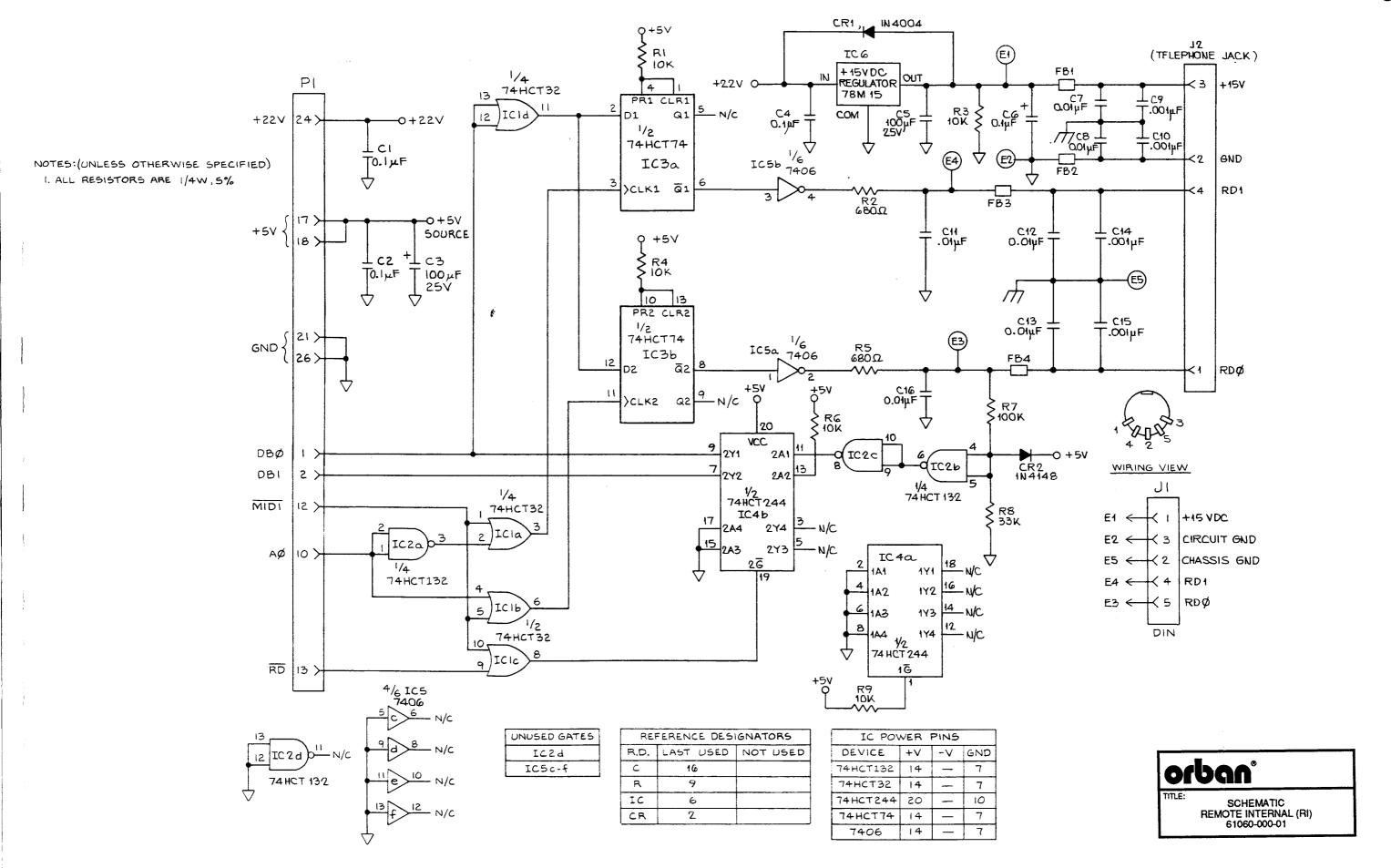
2. DOTTED COMPONENTS TO BE INSTALLED ON <u>SOLDER SIDE</u> AS SHOWN.

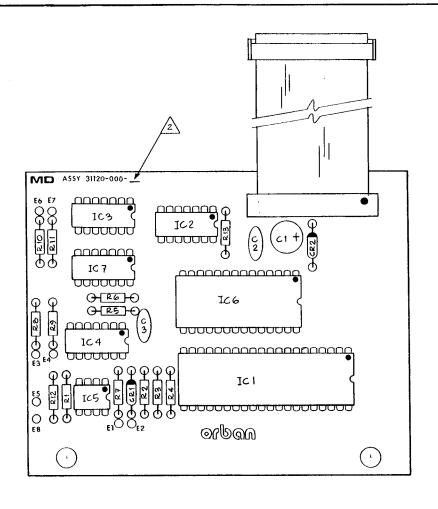
1. TIC MARKS INDICATE PIN #1 OF CONNECTOR, CATHODE OF LED'S.

NOTES: (UNLESS OTHERWISE SPECIFIED)









PEFERENCE WIRELIST

FROM	TO	FUNCTION
EI	J1-4	11/
EZ	J1-5	12
E3	J2-4	THRU
E4	J2-5	THRU
E5	J2-2	GND
E6	J3-4	OUT
E7	J3-5	OUT
E8	13-2	GND

COMPONENT SIDE

2 MARK ASSEMBLY REV. LEVEL IN SPACE PROVIDED

1. TIC MARKS INDICATE PIN# 1 OF IC'S, CATHODE OF DIODE, POS. SIDE OF CAPS & PIN#1 OF CONNECTOR

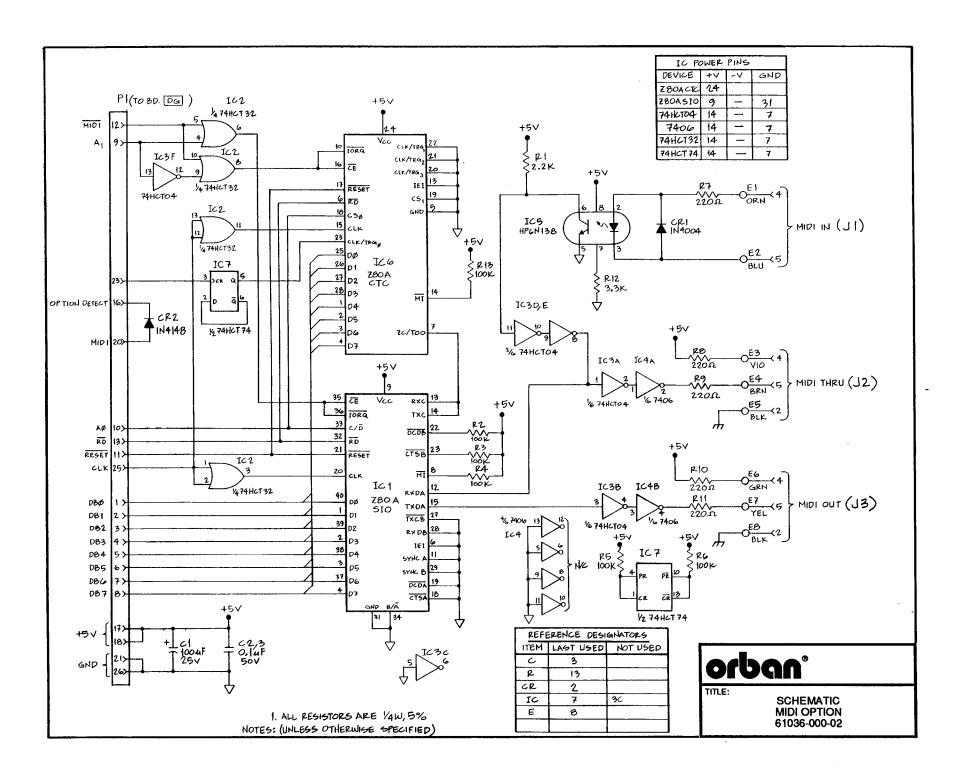
NOTES: (UNLESS OTHERWISE SPECIFIED)

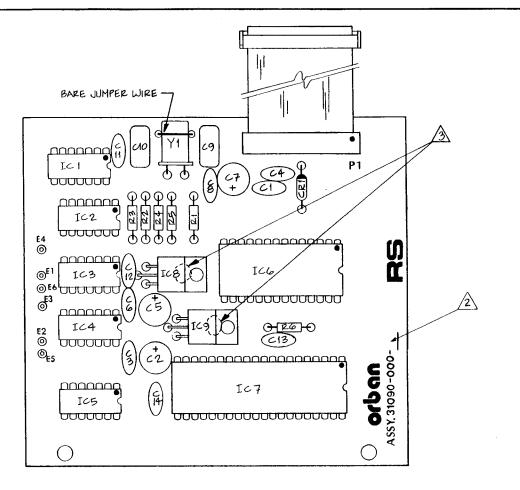


TITLE:

ASSEMBLY DRAWING MIDI OPTION 31120-000-02







REFERENCE WIRELIST

	FROM	TO	FUNCTION
	E	JI-2	T×D
ı	E2	11-3	R×D
	E3	J1-5	CTS
	E4	JI-4	RTS
	E5	J1-6	DSR
	E6	J1-20	DTR
	E7	J1-7	SIG. GND
	E8	J -1	CHAS. GND

COMPONENT SIDE

CEMENT ICE 4 IC9 TO PCB WITH DAB OF GE RTV-162 SILICONE PUBBER

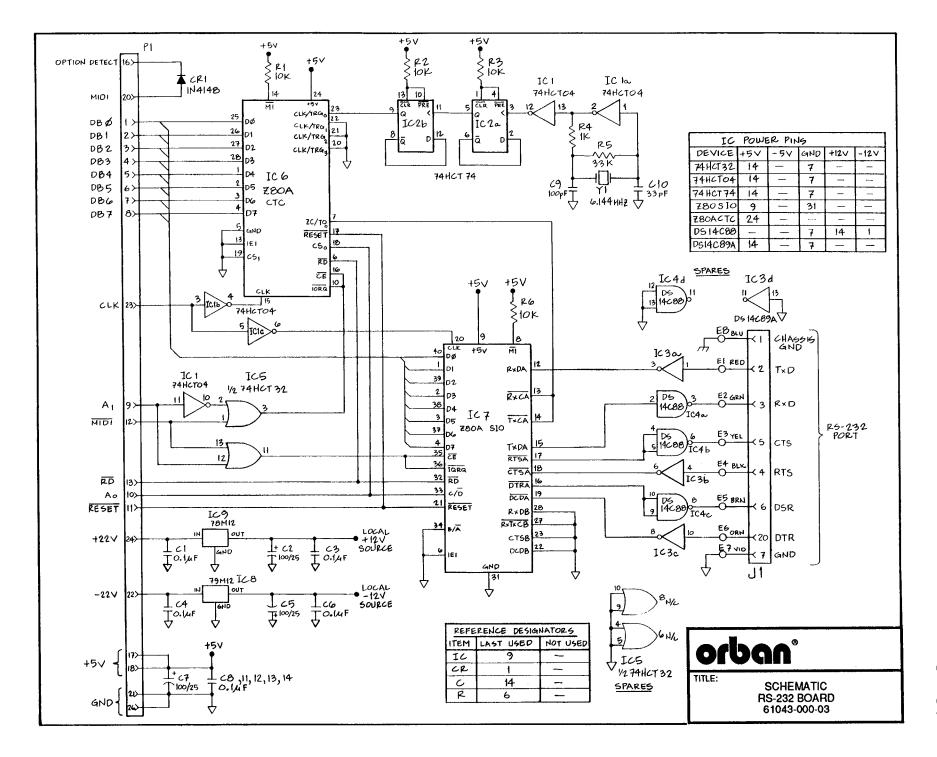
MARK ASSEMBLY REVISION LEVEL, WITH RED MARKER IN SPACE PROVIDED,

1. TIC MARKS INDICATE PIN Nº 1 OF IC'S, CATHOPE OF DIODE, POS, SIDE OF CAPS,, PIN Nº 1 OF CONNECTOR
NOTES: (UNLESS OTHERWISE SPECIFIED)



TITLE:

PC ASSEMBLY RS-232 BOARD 31090-000-02



Abbreviations

Some of the abbreviations used in this manual may not be familiar to all readers:

AGC dBu	automatic gain control 0dBu = 0.775V RMS. For this application, the dBm-into-600Ω scale on voltmeters can be read as if it were calibrated in dBu.
DJ EMI	disk jockey, an announcer who plays records in a club or on the air electromagnetic interference
FCC FET	Federal Communications Commission (USA regulatory agency) field effect transistor
G/R IC	gain reduction integrated circuit integrated circuit integrated circuit distortion")
IM JFET	intermodulation (or "intermodulation distortion") junction field effect transistor
LED N&D	light-emitting diode noise and distortion
RF RFI RMS	radio frequency radio-frequency interference root-mean-square
THD VCA XLR	total harmonic distortion voltage-controlled amplifier a common style of 3-conductor audio connector